Report No. RXA1208-0616HAC01

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ANSI C63.19 TEST REPORT

Product Name	UMTS Dualband / GSM Quadband mobile phone
Model Name	Gemini
Marketing Name	Alcatel OT871A
FCC ID	RAD264
Client	TCT Mobile Limited

TA Technology (Shanghai) Co., Ltd.

GENERAL SUMMARY

Product Name	UMTS Dualband / GSM Quadband mobile phone	Model	Gemini
Report No.	RXA1208-0616HAC01	FCC ID	RAD264
Client	TCT Mobile Limited		
Manufacturer	TCT Mobile Limited		
Reference Standard(s)	ANSI C63.19-2007: American Compatibility between Wireles		
Conclusion	This portable wireless equipment the relevant standards. General Judgment: M3 (RF E	mission) (Stamp)	ee: August 30th, 2012
Comment	The test result only responds	to the measured sar	mple.

Approved by Revised by SAR Manager SAR Engineer

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1. General Information

1.1. Notes of the Test Report

TA Technology (Shanghai) Co., Ltd. guarantees the reliability of the data presented in this test report, which is the results of measurements and tests performed for the items under test on the date and under the conditions stated in this test report and is based on the knowledge and technical facilities available at TA Technology (Shanghai) Co., Ltd. at the time of execution of the test.

TA Technology (Shanghai) Co., Ltd. is liable to the client for the maintenance by its personnel of the confidentiality of all information related to the items under test and the results of the test. This report only refers to the item that has undergone the test.

This report standalone dose not constitute or imply by its own an approval of the product by the certification Bodies or competent Authorities. This report cannot be used partially or in full for publicity and/or promotional purposes without previous written approval of **TA Technology (Shanghai) Co., Ltd.** and the Accreditation Bodies, if it applies.

If the electrical report is inconsistent with the printed one, it should be subject to the latter.

1.2. Testing Laboratory

Company: TA Technology (Shanghai) Co., Ltd.

Address: No.145, Jintang Rd, Tangzhen Industry Park, Pudong Shanghai, China

City: Shanghai Post code: 201201

Country: P. R. China

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1.3. Applicant Information

Company: TCT Mobile Limited

5F, E building, No. 232, Liang Jing Road ZhangJiang High-Tech Park, Pudong Area Address:

Shanghai, P.R. China. 201203

City: Shanghai

Postal Code: 201203

Country: P.R. China

1.4. Manufacturer Information

Company: TCT Mobile Limited

Address: 5F, E building, No. 232, Liang Jing Road ZhangJiang High-Tech Park, Pudong Area

Shanghai, P.R. China. 201203

City: Shanghai

Postal Code: 201203

Country: P.R. China

1.5. Information of EUT

General Information

Device Type:	Portable Device				
Product Name:	UMTS Dualband / GSM Quadband mobile phone				
IMEI:	013160000201662				
Hardware Version:	05	05			
Software Version:	SW980				
Antenna Type:	Internal Antenna				
Device Operating Configurations:					
	GSM 850/GSM 1900; (t	ested)			
Supporting Mode(s):	WCDMA Band II/WCDN	//A Band V; (tested)			
Supporting Mode(s).	GSM 900/GSM 1800; (u	untested)			
	Bluetooth; (untested)				
Test Modulation:	(GSM)GMSK; (WCDMA	A) QPSK			
Device Class:	В				
HSDPA UE Category:	8				
HSUPA UE Category:	6				
	Max Number of Timeslo	ots in Uplink	2		
GPRS Multislot Class(10):	Max Number of Timeslo	ots in Downlink	4		
	Max Total Timeslot		5		
	Max Number of Timeslo	2			
EGPRS Multislot Class(10):	Max Number of Timeslo	4			
	Max Total Timeslot		5		
	Mode	Tx (MHz)	Rx (MHz)		
	GSM 850	824.2 ~ 848.8	869.2 ~ 893.8		
Operating Frequency Range(s):	GSM 1900	1850.2 ~ 1909.8	1930.2 ~ 1989.8		
	WCDMA Band II	1852.4 ~ 1907.6	1932.4 ~ 1987.6		
	WCDMA Band V	826.4 ~ 846.6	871.4 ~ 891.6		
	128-190-251 (G	SM 850) (tested)			
Test Channel:	512-661-810 (GS	SM 1900) (tested)			
(Low - Middle - High)	9262 - 9400 - 9538	(WCDMA Band II) (tes	ited)		
	4132 - 4183 - 4233 (WCDMA Band V) (tested)				
	GSM 850: 4				
Power Class:	GSM 1900: 1				
	WCDMA Band II: 3				
	WCDMA Band V: 3				
	GSM 850: tested with p	ower level 5			
Power Level:	GSM 1900: tested with	power level 0			
. 55. 2575	WCDMA Band II: tested	with power control all u	p bits		
	WCDMA Band V: tested	d with power control all u	ıp bits		

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Auxiliary Equipment Details

Name	Model	Manufacturer	S/N
Battery 1	CAB3120000C3	BAK	BAK2011110800329
Battery 2	CAB3120000C1	BYD	B08606451BA

Equipment Under Test (EUT) is a UMTS Dualband / GSM Quadband mobile phone. The detail about EUT and Lithium Battery is in chapter 1.5 in this report. The device has an internal antenna for GSM/WCDMA Tx/Rx, and the other is BT antenna that is used for Tx/Rx. HAC is tested for GSM 850, GSM 1900, WCDMA Band II and WCDMA Band V. BT mode doesn't have voice capability, and does not operate in the held to ear mode for providing handset service.

The sample under test was selected by the Client.

Components list please refer to documents of the manufacturer.

1.6. The Ambient Conditions during Test

Temperature	Min. = 18°C, Max. = 28 °C			
Relative humidity	Min. = 0%, Max. = 80%			
Ground system resistance	< 0.5 Ω			
Ambient noise is checked and found very low and in compliance with requirement of standards				
Reflection of surrounding objects is minimize	ed and in compliance with requirement of standards.			

1.7. The Total M-rating of each tested band

Mode	Rating
GSM 850	M3
GSM 1900	M3
WCDMA Band II	M4
WCDMA Band V	M4

1.8. Test Date

The test performed on April 23, 2012 and August 19,2012.

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2. Test Information

2.1. Operational Conditions during Test

2.1.1. General Description of Test Procedures

The phone was tested in all normal configurations for the ear use. The EUT is mounted in the device holder equivalent as for classic dosimeter measurements. The acoustic output of the EUT shall coincide with the center point of the area formed by the dielectric wire and the middle bar of the arch's top frame The EUT shall be moved vertically upwards until it touches the frame. The fine adjustment is possible by sliding the complete. The EUT holder is on the yellow base plate of the Test Arch phantom. These test configurations are tested at the high, middle and low frequency channels of each applicable operating mode; for example, GSM, WCDMA (UMTS), CDMA and TDMA.

2.1.2. GSM/WCDMA Test Configuration

A communication link is set up with a System Simulator (SS) by air link, and a call is established. The Absolute Radiofrequency Channel Number (ARFCN) is allocated to 128, 190 and 251 in the case of GSM 850, to 512, 661 and 810 in the case of GSM 1900, to 9262, 9400 and 9538 in the case of WCDMA Band II, to 4132, 4183 and 4233 in the case of WCDMA Band V. The EUT is commanded to operate at maximum transmitting power. Using E5515C the power lever is set to "5" for GSM 850, set to "0" for GSM 1900. Set to all up bits for WCDMA. The test in the bands of GSM 850/GSM 1900 and WCDMA Band II /WCDMA Band V are performed in the mode of speech transfer function.

2.2. HAC RF Measurements System Configuration

2.2.1. HAC Measurement Set-up

These measurements are performed using the DASY5 automated dosimetric assessment system. It is made by Schmid & Partner Engineering AG (SPEAG) in Zurich, Switzerland. It consists of high precision robotics system (Stäubli), robot controller, Intel Core2 computer, near-field probe, probe alignment sensor. The robot is a six-axis industrial robot performing precise movements. Cell controller systems contain the power supply, robot controller, teach pendant (Joystick) and remote control, and are used to drive the robot motors. The Stäubli Robot is connected to the cell controller to allow software manipulation of the robot. A data acquisition electronic (DAE) circuit performs the signal amplification; signal multiplexing, AD-conversion, offset measurements, mechanical surface detection, collision detection, etc. is connected to the Electro-optical coupler (EOC). The EOC performs the conversion from the optical into digital electric signal of the DAE and transfers data to the PC plug-in card.

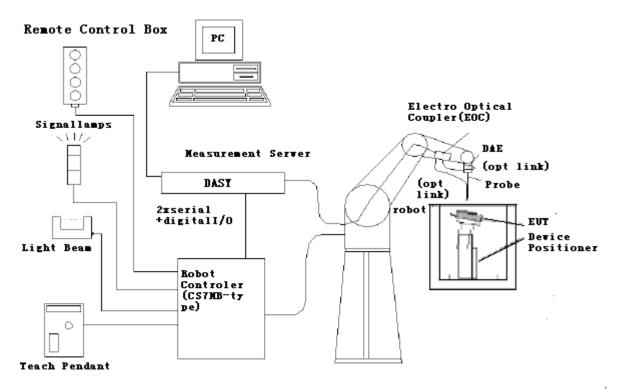


Figure 1 HAC Test Measurement Set-up

The DAE4 consists of a highly sensitive electrometer-grade preamplifier with auto-zeroing, a channel and gain-switching multiplexer, a fast 16 bit AD-converter and a command decoder and control logic unit. Transmission to the PC-card is accomplished through an optical downlink for data and status information and an optical uplink for commands and clock lines. The mechanical probe mounting device includes two different sensor systems for frontal and sidewise probe contacts. They are also used for mechanical surface detection and probe collision detection. The robot uses its own controller with a built in VME-bus computer.

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2.2.2. Probe System

The HAC measurements were conducted with the E-Field Probe ER3DV6 and the H-Field Probe H3DV6 (manufactured by SPEAG), designed in the classical triangular configuration and optimized for dosimetric evaluation.

E-Field Probe Description

Construction One dipole parallel, two dipoles normal to probe

axis

Built-in shielding against static charges

PEEK enclosure material

Calibration In air from 100 MHz to 3.0 GHz (absolute accuracy

 $\pm 6.0\%$, k=2)

Frequency 40 MHz to > 6 GHz (can be extended to < 20 MHz)

Linearity: ± 0.2 dB (100 MHz to 3 GHz)

Directivity \pm 0.2 dB in air (rotation around probe axis)

± 0.4 dB in air (rotation normal to probe axis)

Dynamic Range 2 V/m to > 1000 V/m; Linearity: ± 0.2 dB

Dimensions Overall length: 330 mm (Tip: 16 mm)

Tip diameter: 8 mm (Body: 12 mm)

Distance from probe tip to dipole centers: 2.5 mm

Application General near-field measurements up to 6 GHz

Field component measurements

Fast automatic scanning in phantoms

H-Field Probe Description

Construction Three concentric loop sensors with 3.8 mm loop

diameters

Resistively loaded detector diodes for linear

response

Built-in shielding against static charges

PEEK enclosure material (resistant to organic

solvents, e.g., glycolether)

Frequency 200 MHz to 3 GHz (absolute accuracy \pm 6.0%, k=2);

Output linearized

Directivity $\pm 0.2 \text{ dB (spherical isotropy error)}$

Dynamic Range 10 mA/m to 2 A/m at 1 GHz

E-Field < 10% at 3 GHz (for plane wave)

Interference

Dimensions Overall length: 330 mm (Tip: 40 mm)

Tip diameter: 6 mm (Body: 12 mm)

Distance from probe tip to dipole centers: 3 mm



Figure 2 ER3DV6 E-field
Probe

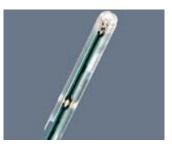


Figure 3 H3DV6 H-field Probe

Application General magnetic near-field measurements up to 3

GHz (in air or liquids)

Field component measurements Surface current measurements

Low interaction with the measured field

2.2.3. Test Arch Phantom & Phone Positioner

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The Test Arch phantom should be positioned horizontally on a stable surface. Reference markings on the Phantom allow the complete setup of all predefined phantom positions and measurement grids by manually teaching three points in the robot. It enables easy and well defined positioning of the phone and validation dipoles as well as simple teaching of the robot (Dimensions: $370 \times 370 \times$

The Device reference point is set for the EUT at 6.3 mm, the Grid reference point is on the upper surface at the origin of the coordinates, and the "user point \Height Check 0.5 mm" is 0.5mm above the center, allowing verication of the gap of 0.5mm while the probe is positioned there.

The Phone Positioner supports accurate and reliable positioning of any phone with effect on near field <±0.5 dB.

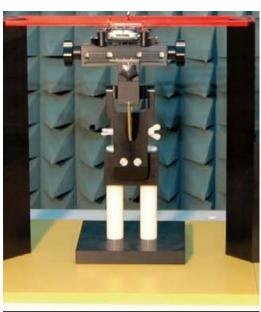


Figure 4 HAC Phantom & Device Holder

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2.3. RF Test Procedures

The evaluation was performed with the following procedure:

- 1. Confirm proper operation of the field probe, probe measurement system and other instrumentation and the positioning system.
- 2. Position the WD in its intended test position. The gauge block can simplify this positioning. Note that a separate E-field and H-field gauge block will be needed if the center of the probe sensor elements is at different distances from the tip of the probe.
- 3. Configure the WD normal operation for maximum rated RF output power, at the desired channel and other operating parameters (e.g., test mode), as intended for the test.
- 4. The center sub-grid shall center on the center of the axial measurement point or the acoustic output, as appropriate. Locate the field probe at the initial test position in the 50 mm by 50 mm grid, which is contained in the measurement plane. If the field alignment method is used, align the probe for maximum field reception.
- 5. Record the reading.
- 6. Scan the entire 50 mm by 50 mm region in equally spaced increments and record the reading at each measurement point. The grid is 5 cm by 5 cm area that is divided into 9 evenly sized blocks or sub-grids. The distance between measurement points shall be sufficient to assure the identification of the maximum reading.
- 7. Identify the five contiguous sub-grids around the center sub-grid with the lowest maximum field strength readings. Thus the six areas to be used to determine the WD's highest emissions are identified and outlined for the final manual scan. Please note that a maximum of five blocks can be excluded for both E-field and H-field measurements for the WD output being measured. Stated another way, the center sub-grid and three others must be common to both the E-field and H-field measurements.
- 8. Identify the maximum field reading within the non-excluded sub-grids identified in Step 7.
- 9. Convert the maximum field strength reading identified in Step 8 to V/m or A/m, as appropriate. For probes which require a probe modulation factor, this conversion shall be done using the appropriate probe modulation factor and the calibration.
- 10. Repeat Step 1 through Step 10 for both the E-field and H-field measurements.
- 11. Compare this reading to the categories in ANSI C63.19 Clause 7 and record the resulting category. The lowest category number listed in 7.2, Table 7.4, or Table 7.5 obtained in Step 10 for either E- or H-field determines the M category for the audio coupling mode assessment. Record the WD category rating.



Figure 5 WD reference and plane for RF emission measurements

2.4. System Check

Validation Procedure

Place a dipole antenna meeting the requirements given in ANSI C63.19 D.5 in the position normally occupied by the WD. The dipole antenna serves as a known source for an electrical and magnetic output. Position the E-field and H-field probes so that:

The probes and their cables are parallel to the coaxial feed of the dipole antenna.

The probe cables and the coaxial feed of the dipole antenna approach the measurement area from opposite directions.

The center point of the probe element(s) are 10 mm from the closest surface of the dipole elements. Validation was performed to verify that measured E-field and H-field values are within +/-25% from the target refenence values provided by the manufacturer. "Values within +/-25% are acceptable. Of which 12% is deviation and 13% is measurement uncertainty."

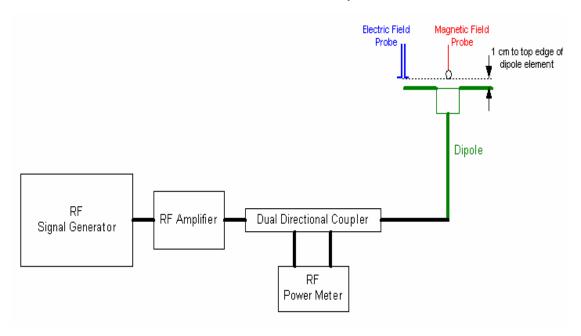


Figure 6 Dipole Validation Setup

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Dipole Measurement Summary

	E-Field Scan						
Mode	Frequency (MHz)	Input Power (mW)	Value	Value			
			Target ¹ Value(V/m)	161.4	February 21,2012		
CW	835	100	Measured ² Value(V/m)	165.0	April 23, 2012		
			Value Target¹ Value(V/m) 161.4 Measured² Value(V/m) 165.0 Deviation³(%) 2.23 Target¹ Value(V/m) 143.4 Measured² Value(V/m) 139.9 Deviation³(%) -2.44 Measured² Value(V/m) 140.9 Deviation³(%) 1.74 H-Field Scan Value Target¹ Value(A/m) 0.460 Measured² Value(A/m) 0.439 Deviation³(%) -4.57 Target¹ Value(A/m) 0.470 Measured² Value(A/m) 0.456 Deviation³(%) -2.98	2.23	1		
			Target ¹ Value(V/m)	143.4	February 21,2012		
			Measured ² Value(V/m)	139.9	April 23, 2012		
CW	1880	100	Deviation ³ (%)	-2.44	/		
			Measured ² Value(V/m)	140.9	August 19, 2012		
			Deviation ³ (%)	1.74	/		
			H-Field Scan				
Mode	Frequency (MHz)	Input Power (mW)	Value		Test Date		
			Target ¹ Value(A/m)	0.460	February 21,2012		
CW	835	100	Measured ² Value(A/m)	0.439	April 23, 2012		
			Deviation ³ (%)	-4.57	/		
			Target ¹ Value(A/m)	0.470	February 21,2012		
			Measured ² Value(A/m)	0.456	April 23, 2012		
CW	1880	100	Deviation ³ (%)	-2.98	1		
			Measured ² Value(A/m)	0.463	August 19, 2012		
	1		Deviation ³ (%)	-1.50			

Notes: 1. Target value is provided by SPEAD in the calibration certificate of specific dipoles.

- 2. Please refer to the attachment for detailed measurement data and plot.
- 3. Deviation (%) = 100 * (Measured value minus Target value) divided by Target value.

2.5. Probe Modulation Factor

The Probe Modulation Factor (PMF) is defined as the ratio of the field readings for a CW and a modulated signal with the equivalent Field Envelope Peak as defined in ANSI C63.19 (Chapter C.3.1). Calibration shall be made of the modulation response of the probe and its instrumentation chain. This Calibration shall be performed with the field probe, attached to the instrumentation that is to be used with it during the measurement. The response of the probe system to a CW field at the frequency(s) of interest is compared to its response to a modulated signal with equal peak amplitude. The field level of the test signals shall be more than 10dB above the ambient level and the noise floor of the instrumentation being used. The ratio of the CW reading to that taken with a modulated field shall be applied to the readings taken of modulated fields of the specified type.

Modulation Factor Test Procedure

This may be done using the following procedure:

- 1. Fix the field probe in a set location relative to a field generating device, such as the reference dipole antenna.
- 2. Illuminate the probe using the wireless device connected to the reference dipole with a test signal at the intended measurement frequency, Ensure there is sufficient field coupling between the probe and the antenna so the resulting reading is greater than 10 dB above the probe system noise floor but within the systems operating range.
- 3. Record the amplitude applied to the antenna during transmission and the field strength measured by the E-field probe located near the tip of the dipole antenna
- 4. Replace the wireless device with an RF signal generator producing an unmodulated CW signal and set to the wireless device operating frequency.
- 5. Set the amplitude of the unmodulated signal to equal that recorded from the wireless device.
- 6. Record the reading of the probe measurement system of the unmodulated signal.
- 7. The ratio, in linear units, of the probe reading in Step 6 to the reading in Step 3 is the E-field modulation factor. $PMF_E = E_{CW} / E_{mod} (PMF_H = H_{CW} / H_{mod})$
- 8. Repeat the previous steps using the H-field probe, except locate the probe at the center of the dipole.

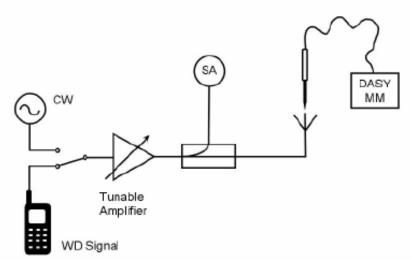


Figure 7 Probe Modulation Factor Test Setup

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PMF

Band	E-Field Probe Modulation Factor	H-Field Probe Modulation Factor
GSM 850	2.81	2.75
GSM 1900	2.84	2.84
WCDMA Band II	1.03	1.01
WCDMA Band V	1.03	1.01

2.6. Conducted Output Power Measurement

Summary

The EUT is tested using an E5515C communications tester as controller unit to set test channels and maximum output power to the DUT, as well as for measuring the conducted power. Conducted output power was measured using an integrated RF connector and attached RF cable. This result contains conducted output power for the EUT.

Conducted Power Results

GSM 850	Co	onducted Power(dBm)		
GSIW 650	Channel 128	Channel 190	Channel 251	
Test Results	33.52	33.33	33.21	
GSM 1900	Co	onducted Power(dBm)		
G3W 1900	Channel 512	Channel 661	Channel 810	
Test Results	29.91	30.07	30.76	
WCDMA Band II	Conducted Power(dBm)			
WCDMA Balld II	Channel 9262	Channel 9400	Channel 9538	
Test Results	22.98	22.88	22.94	
WCDMA Board V	Co	onducted Power(dBm)		
WCDMA Band V	Channel 4132	Channel 4183	Channel 4233	
Test Results	23.54	23.4	23.28	

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3. Test Results

3.1. ANSI C63.19-2007 Limits

Category		Telephone RF parameters < 960 MHz				
Near field	AWF	E-field emis	sions	H-field emissions		
Catagory M1	0	631.0 to 1122.0	V/m	1.91 to 3.39	A/m	
Category M1	- 5	473.2 to 841.4	V/m	1.43 to 2.54	A/m	
Catagon, M2	0	354.8 to 631.0	V/m	1.07 to 1.91	A/m	
Category M2	-5	266.1 to 473.2	V/m	0.80 to 1.43	A/m	
Ontonon MO	0	199.5 to 354.8	V/m	0.60 to 1.07	A/m	
Category M3	-5	149.6 to 266.1	V/m	0.45 to 0.80	A/m	
OntonomiNA	0	< 199.5	V/m	< 0.60	A/m	
Category M4	-5	< 149.6	V/m	< 0.45	A/m	
Category		Teleph	one RF paran	neters > 960 MHz		
Near field	AWF	E-field emis	sions	H-field emissions		
Cotogon, M1	0	199.5 to 354.8	V/m	0.60 to 1.07	A/m	
Category M1	-5	149.6 to 266.1	V/m	0.45 to 0.80	A/m	
Cotomoni MO	0	112.2 to 199.5	V/m	0.34 to 0.60	A/m	
Category M2	-5	84.1 to 149.6	V/m	0.25 to 0.45	A/m	
Cotogon: M2	0	63.1 to 112.2	V/m	0.19 to 0.34	A/m	
Category M3	-5	47.3 to 84.1	V/m	0.14 to 0.25	A/m	
Cotogon, M4	0	< 63.1	V/m	< 0.19	A/m	
Category M4	-5	< 47.3	V/m	< 0.14	A/m	

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3.2. Summary Test Results

GSM 850 Results

		E-Field with B	attery 1		
Channel	el Frequency (MHz) Peak Field (V/m) Power Drift (dB) Rating				
High/251	848.8	193.0	-0.034	М3	Figure 14
Middle/190	836.6	196.0	-0.043	МЗ	Figure 15
Low/128	824.2	182.8	-0.032	МЗ	Figure 16
E-Field with Battery 2					
Middle/190	836.6	188.6	-0.009	МЗ	Figure 17
		H-Field with B	attery 1		
Channel	Frequency (MHz)	Peak Field (A/m)	Power Drift (dB)	Rating	Graph Results
High/251	848.8	0.275	-0.029	M4	Figure 18
Middle/190	836.6	0.272	0.000	M4	Figure 19
Low/128	824.2	0.258	-0.067	M4	Figure 20
		H-Field with B	attery 2		
High/251	848.8	0.272	-0.007	M4	Figure 21

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GSM 1900 Results

	E-Field with Battery 1						
Channel	Frequency (MHz)	Peak Field (V/m)	Power Drift (dB)	Rating	Graph Results		
High/810	1909.8	71.1	0.145	МЗ	Figure 22		
Middle/661	1880	74.4	0.083	МЗ	Figure 23		
Low/512	1850.2	79.0	-0.031	МЗ	Figure 24		
	E-Field with Battery 2						
Low/512	1850.2	76.2	0.047	МЗ	Figure 25		
		H-Field with B	attery 1				
Channel	Frequency (MHz)	Peak Field (A/m)	Power Drift (dB)	Rating	Graph Results		
High/810	1909.8	0.203	0.000	МЗ	Figure 26		
Middle/661	1880	0.217	-0.021	МЗ	Figure 27		
Low/512	1850.2	0.228	-0.063	МЗ	Figure 28		
	H-Field with Battery 2						
Low/512	1850.2	0.233	-0.017	МЗ	Figure 29		

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WCDMA Band II Results

E-Field with Battery 1						
Channel	Frequency (MHz)	Peak Field (V/m)	Power Drift (dB)	Rating	Graph Results	
High/9538	1907.6	37.5	-0.131	M4	Figure 30	
Middle/9400	1880	37.8	-0.057	M4	Figure 31	
Low/9262	1852.4	30.7	-0.002	M4	Figure 32	
	E-Field with Battery 2					
Middle/9400	1880	38.1	-0.072	M4	Figure 33	
		H-Field with Ba	attery 1			
Channel	Frequency (MHz)	Peak Field (A/m)	Power Drift (dB)	Rating	Graph Results	
High/9538	1907.6	0.095	0.017	M4	Figure 34	
Middle/9400	1880	0.106	-0.019	M4	Figure 35	
Low/9262	1852.4	0.089	-0.002	M4	Figure 36	
	H-Field with Battery 2					
Middle/9400	1880	0.105	-0.003	M4	Figure 37	

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WCDMA Band V Results

	E-Field with Battery 1						
Channel	Frequency (MHz)	Peak Field (V/m)	Power Drift (dB)	Rating	Graph Results		
High/4233	846.6	77.4	-0.021	M4	Figure 38		
Middle/4183	836.6	71.3	-0.034	M4	Figure 39		
Low/4132	826.4	73.3	-0.012	M4	Figure 40		
	E-Field with Battery 2						
High/4233	846.6	77.3	-0.003	M4	Figure 41		
		H-Field with Ba	attery 1				
Channel	Frequency (MHz)	Peak Field (A/m)	Power Drift (dB)	Rating	Graph Results		
High/4233	846.6	0.107	0.031	M4	Figure 42		
Middle/4183	836.6	0.098	-0.051	M4	Figure 43		
Low/4132	826.4	0.100	-0.007	M4	Figure 44		
	H-Field with Battery 2						
High/4233	846.6	0.111	-0.020	M4	Figure 45		

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4. Measurement Uncertainty

No.	Error source	Туре	Uncertainty Value (%)	Prob. Dist.	k	c _{i/} E	c₁∖H	Standard Uncertainty (%) $u_i^{'}$ (%)	Standard Uncertainty (%) $u_i^{'}$ (%) H	Degree of freedom V _{eff} or v _i
		I		Measu	rement	System)			1
1	Probe Calibration	В	5.1	N	1	1	1	5.1	5.1	∞
2	Axial Isotropy	В	4.7	R	$\sqrt{3}$	1	1	2.7	2.7	∞
3	Sensor Displacement	В	16.5	R	$\sqrt{3}$	1	0.145	9.5	1.4	∞
4	Boundary Effects	В	2.4	R	$\sqrt{3}$	1	1	1.4	1.4	∞
5	Test Arch	В	7.2	R	$\sqrt{3}$	1	0	4.1	0	∞
6	Linearity	В	4.7	R	$\sqrt{3}$	1	1	2.7	2.7	∞
7	Scaling to Peak Envelope Power	В	2.0	R	$\sqrt{3}$	1	1	1.2	1.2	∞
8	System Detection Limit	В	1.0	R	$\sqrt{3}$	1	1	0.6	0.6	∞
9	Readout Electronics	В	0.3	N	1	1	1	0.3	0.3	∞
10	Response Time	В	0.8	R	$\sqrt{3}$	1	1	0.5	0.5	∞
11	Integration Time	В	2.6	R	$\sqrt{3}$	1	1	1.5	1.5	8
12	RF Ambient Conditions	В	3.0	R	$\sqrt{3}$	1	1	1.7	1.7	∞
13	RF Reflections	В	12.0	R	$\sqrt{3}$	1	1	6.9	6.9	∞
14	Probe Positioner	В	1.2	R	$\sqrt{3}$	1	0.67	0.7	0.5	∞
15	Probe Positioning	Α	4.7	R	$\sqrt{3}$	1	0.67	2.7	1.8	∞
16	Extra. And Interpolation	В	1.0	R	$\sqrt{3}$	1	1	0.6	0.6	∞
Test	Test Sample Related									
17	Device Positioning Vertical	В	4.7	R	$\sqrt{3}$	1	0.67	2.7	1.8	∞
18	Device Positioning Lateral	В	1.0	R	$\sqrt{3}$	1	1	0.6	0.6	∞

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19	Device Holder and Phantom	В	2.4	R	$\sqrt{3}$	1	1	1.4	1.4	∞
20	Power Drift	В	5.0	R	$\sqrt{3}$	1	1	2.9	2.9	8
	Phantom and Setup related									
21	Phantom Thickness	В	2.4	R	$\sqrt{3}$	1	0.67	1.4	0.9	∞
Com	Combined standard uncertainty (%)							15.19	10.82	
Expa	Expanded Std. uncertainty on power (K=2)							30.38	21.64	
Expa	nded Std. uncertainty or	n field (K	=2)					15.19	10.82	

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5. Main Test Instruments

No.	Name	Туре	Serial Number	Calibration Date	Valid Period
01	Power meter	Agilent E4417A	GB41291714	March 11, 2012	One year
02	Power sensor	Agilent N8481H	MY50350004	September 25, 2011	One year
03	Signal Generator	HP 8341B	2730A00804	September 12, 2011	One year
04	Amplifier	IXA-020	0401	No Calibration R	equested
05	BTS	E5515C	MY48360988	December 2, 2011	One year
06	E-Field Probe	ER3DV6	2303	February 21, 2012	One year
07	H-Field Probe	H3DV6	6138	February 21, 2012	One year
08	DAE	DAE4	1317	January 23, 2012	One year
09	Validation Kit 835MHz	CD835V3	1133	February 21, 2012	One year
10	Validation Kit 1880MHz	CD1880V3	1115	February 21, 2012	One year
11	Hygrothermograph	WS-1	64591	September 28, 2011	One year

*****END OF REPORT *****

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ANNEX A: System Check Results

HAC_System Performance Check at 835MHz_E

DUT: Dipole 835 MHz; Type: CD835V3; SN:1133

Date/Time: 4/23/2012 3:40:12 PM

Communication System: CW; Frequency: 835 MHz;Duty Cycle: 1:1 Medium parameters used: σ = 0 mho/m, ϵ_r = 1; ρ = 1000 kg/m³

Ambient Temperature:22.3 $^{\circ}$ C Phantom section: RF Section

DASY5 Configuration:

Probe: ER3DV6 - SN2303; ConvF(1, 1, 1); Calibrated: 2/21/2012

Electronics: DAE4 Sn1317; Calibrated: 1/23/2012

Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA

Measurement SW: DASY5, V5.2 Build 162; SEMCAD X Version 14.0 Build 59

E Scan - measurement distance from the probe sensor center to CD835 Dipole = 10mm 2/Hearing Aid Compatibility Test (41x361x1): Measurement grid: dx=5mm, dy=5mm

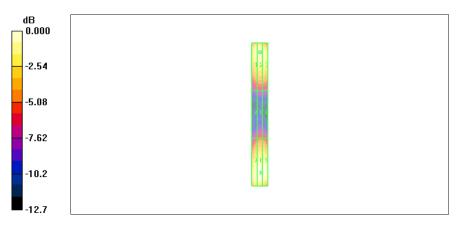
Maximum value of peak Total field = 165.0 V/m

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm
Reference Value = 121.4 V/m; Power Drift = 0.016 dB
Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1	Grid 2	Grid 3
149.6 M4	154.8 M4	150.6 M4
Grid 4	Grid 5	Grid 6
83.5 M4	88.2 M4	87.7 M4
Grid 7	Grid 8	Grid 9
156.2 M4	165.0 M4	164.3 M4



0 dB = 165.0V/m

Figure 8 System Performance Check 835MHz_E

HAC_System Performance Check at 835MHz_H

DUT: Dipole 835 MHz; Type: CD835V3; SN: 1133

Date/Time: 4/23/2012 3:40:52 PM

Communication System: CW; Frequency: 835 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 1$ kg/m³

Ambient Temperature:22.3 $^{\circ}$ C Phantom section: RF Section

DASY5 Configuration:

Probe: H3DV6 - SN6138; ; Calibrated: 2/21/2012 Electronics: DAE4 Sn1317; Calibrated: 1/23/2012

Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA

Measurement SW: DASY5, V5.2 Build 162; SEMCAD X Version 14.0 Build 59

H Scan - measurement distance from the probe sensor center to CD835 Dipole = 10mm/Hearing Aid Compatibility Test (41x361x1): Measurement grid: dx=5mm, dy=5mm

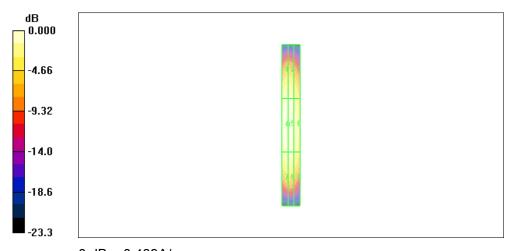
Maximum value of peak Total field = 0.439 A/m

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm Reference Value = 0.451 A/m; Power Drift = 0.013 dB **Hearing Aid Near-Field Category: M4 (AWF 0 dB)**

Peak H-field in A/m

Grid 1	Grid 2	Grid 3
0.384 M4	0.385 M4	0.340 M4
Grid 4	Grid 5	Grid 6
0.438 M4	0.439 M4	0.390 M4
Grid 7	Grid 8	Grid 9
0.386 M4	0.392 M4	0.347 M4



0 dB = 0.439A/m

Figure 9 System Performance Check 835MHz_H

HAC_System Performance Check at 1880MHz_E

DUT: Dipole 1880 MHz; Type: CD1880V3; SN: 1115

Date/Time: 4/23/2012 12:40:25 PM

Communication System: CW; Frequency: 1880 MHz;Duty Cycle: 1:1 Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 1000$ kg/m³

Ambient Temperature:22.3 $^{\circ}$ C Phantom section: RF Section

DASY5 Configuration:

Probe: ER3DV6 - SN2303; ConvF(1, 1, 1); Calibrated: 2/21/2012

Electronics: DAE4 Sn1317; Calibrated: 1/23/2012

Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA

Measurement SW: DASY5, V5.2 Build 162; SEMCAD X Version 14.0 Build 59

E Scan - measurement distance from the probe sensor center to CD1880 Dipole = 10mm/Hearing Aid Compatibility Test (41x181x1): Measurement grid: dx=5mm, dy=5mm

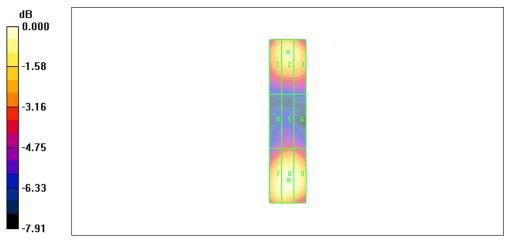
Maximum value of peak Total field = 139.9 V/m

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm Reference Value = 140.4 V/m; Power Drift = -0.024 dB **Hearing Aid Near-Field Category: M2 (AWF 0 dB)**

Peak E-field in V/m

Grid 1	Grid 2	Grid 3
125.4 M2	130.9 M2	126.9 M2
Grid 4	Grid 5	Grid 6
87.9 M3	92.3 M3	90.9 M3
Crid 7	Grid 8	Grid 9
Grid 7	Giiu o	Onu 9



0 dB = 139.9V/m

Figure 10 System Performance Check 1880MHz_E

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HAC_System Performance Check at 1880MHz_E

DUT: Dipole 1880 MHz; Type: CD1880V3; SN: 1115

Date/Time: 8/19/2012 10:29:05 AM

Communication System: CW; Frequency: 1880 MHz;Duty Cycle: 1:1 Medium parameters used: σ = 0 mho/m, ϵ_r = 1; ρ = 1000 kg/m³

Ambient Temperature:22.3 $^{\circ}\mathrm{C}$ Phantom section: RF Section

DASY5 Configuration:

Probe: ER3DV6 - SN2303; ConvF(1, 1, 1); Calibrated: 2/21/2012

Electronics: DAE4 Sn1317; Calibrated: 1/23/2012

Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA

Measurement SW: DASY5, V5.2 Build 162; SEMCAD X Version 14.0 Build 59

E Scan - measurement distance from the probe sensor center to CD1880 Dipole = 10mm/Hearing Aid Compatibility Test (41x181x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 140.9 V/m

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm Reference Value = 139.7 V/m; Power Drift = -0.027 dB **Hearing Aid Near-Field Category: M2 (AWF 0 dB)**

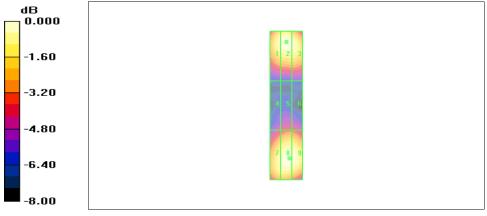
Peak E-field in V/m

Grid 1	Grid 2	Grid 3
134.8 M2	140.9 M2	136.2 M2
Grid 4	Grid 5	Grid 6
87.2 M3	93.7 M3	93.3 M3
Grid 7	Grid 8	Grid 9
131.0 M2	138.5 M2	137.8 M2

Cursor:

Total = 140.9 V/m E Category: M2

Location: 0, -38.5, 4.7 mm



0 dB = 140.9 V/m

Figure 11 System Performance Check 1880MHz_E

HAC_System Performance Check at 1880MHz_H

DUT: Dipole 1880 MHz; Type: CD1880V3; SN: 1115

Date/Time: 4/23/2012 2:10:37 PM

Communication System: CW; Frequency: 1880 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 1$ kg/m³

Ambient Temperature:22.3 $^{\circ}$ C Phantom section: RF Section

DASY5 Configuration:

Probe: H3DV6 - SN6138; ; Calibrated: 2/21/2012 Electronics: DAE4 Sn1317; Calibrated: 1/23/2012

Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA

Measurement SW: DASY5, V5.2 Build 162; SEMCAD X Version 14.0 Build 59

H Scan - measurement distance from the probe sensor center to Dipole = 10mm/Hearing Aid

Compatibility Test (41x181x1): Measurement grid: dx=5mm, dy=5mm

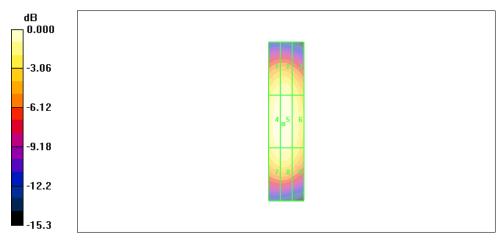
Maximum value of peak Total field = 0.456 A/m

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm Reference Value = 0.478 A/m; Power Drift = -0.003 dB Hearing Aid Near-Field Category: M2 (AWF 0 dB)

Peak H-field in A/m

Grid 1	Grid 2	Grid 3
0.409 M2	0.415 M2	0.377 M2
Grid 4	Grid 5	Grid 6
0.450 M2	0.456 M2	0.416 M2
Grid 7	Grid 8	Grid 9
0.415 M2	0.421 M2	0.380 M2



0 dB = 0.456A/m

Figure 12 System Performance Check 1880MHz_H

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HAC_System Performance Check at 1880MHz_H

DUT: Dipole 1880 MHz; Type: CD1880V3; SN: 1115

Date/Time: 8/19/2012 9:00:09 AM

Communication System: CW; Frequency: 1880 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 1$ kg/m³

Ambient Temperature:22.3 $^{\circ}\mathrm{C}$ Phantom section: RF Section

DASY5 Configuration:

Probe: H3DV6 - SN6138; ; Calibrated: 2/21/2012 Electronics: DAE4 Sn1317; Calibrated: 1/23/2012

Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA

Measurement SW: DASY5, V5.2 Build 162; SEMCAD X Version 14.0 Build 59

H Scan - measurement distance from the probe sensor center to Dipole = 10mm/Hearing Aid

Compatibility Test (41x181x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.463 A/m

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm Reference Value = 0.489 A/m; Power Drift = 0.011 dB **Hearing Aid Near-Field Category: M2 (AWF 0 dB)**

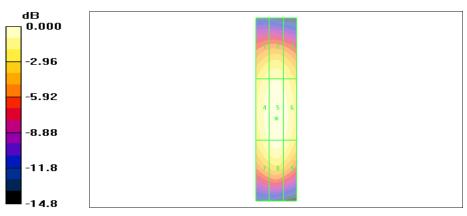
Peak H-field in A/m

Grid 1	Grid 2	Grid 3
0.398 M2	0.412 M2	0.393 M2
Grid 4	Grid 5	Grid 6
0.444 M2	0.463 M2	0.441 M2
Grid 7	Grid 8	Grid 9
0.418 M2	0.441 M2	0.417 M2

Cursor:

Total = 0.463 A/m H Category: M2

Location: 0, 4.5, 4.7 mm



0 dB = 0.463A/m

Figure 13 System Performance Check 1880MHz_H

ANNEX B: Graph Results

HAC RF E-Field GSM 850 High (Battery 1)

Date/Time: 4/23/2012 9:00:15 PM

Communication System: GSM 850; Frequency: 848.8 MHz; Duty Cycle: 1:8.3

Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 1000$ kg/m³

Ambient Temperature:22.3 $^{\circ}\text{C}$ Phantom section: RF Section

DASY5 Configuration:

Probe: ER3DV6 - SN2303; ConvF(1, 1, 1); Calibrated: 2/21/2012

Electronics: DAE4 Sn1317; Calibrated: 1/23/2012

Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA

Measurement SW: DASY5, V5.2 Build 162; SEMCAD X Version 14.0 Build 59

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device High/Hearing Aid Compatibility

Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

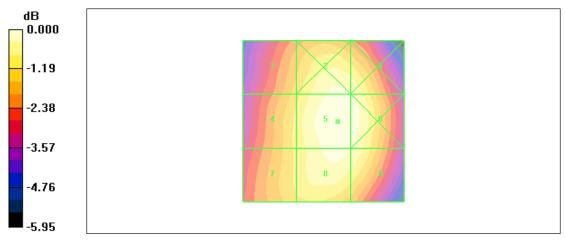
Maximum value of peak Total field = 193.0 V/m

Probe Modulation Factor = 2.81

Device Reference Point: 0.000, 0.000, -6.30 mm Reference Value = 87.8 V/m; Power Drift = -0.034 dB **Hearing Aid Near-Field Category: M3 (AWF -5 dB)**

Peak E-field in V/m

Grid 1	Grid 2	Grid 3
164.9 M3	187.9 M3	185.7 M3
Grid 4	Grid 5	Grid 6
171.1 M3	193.0 M3	190.6 M3
Grid 7	Grid 8	Grid 9
170.3 M3	188.3 M3	185.0 M3



0 dB = 193.0V/m

Figure 14 HAC RF E-Field GSM 850 Channel 251

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HAC RF E-Field GSM 850 Middle (Battery 1)

Date/Time: 4/23/2012 9:24:34 PM

Communication System: GSM 850; Frequency: 836.6 MHz; Duty Cycle: 1:8.3

Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 1000$ kg/m³

Ambient Temperature:22.3 $^{\circ}$ C Phantom section: RF Section

DASY5 Configuration:

Probe: ER3DV6 - SN2303; ConvF(1, 1, 1); Calibrated: 2/21/2012

Electronics: DAE4 Sn1317; Calibrated: 1/23/2012

Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA

Measurement SW: DASY5, V5.2 Build 162; SEMCAD X Version 14.0 Build 59

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device Middle/Hearing Aid

Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

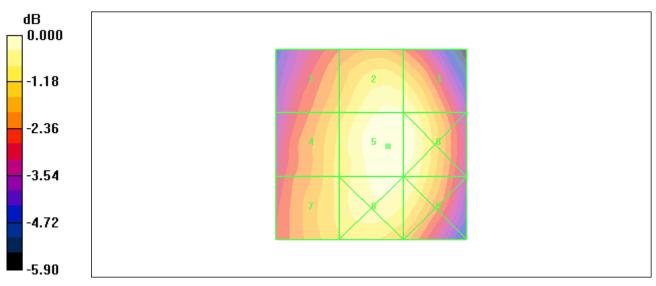
Maximum value of peak Total field = 196.0 V/m

Probe Modulation Factor = 2.81

Device Reference Point: 0.000, 0.000, -6.30 mm Reference Value = 88.0 V/m; Power Drift = -0.043 dB Hearing Aid Near-Field Category: M3 (AWF -5 dB)

Peak E-field in V/m

Grid 1	Grid 2	Grid 3
166.8 M3	189.9 M3	187.7 M3
Grid 4	Grid 5	Grid 6
173.9 M3	196.0 M3	193.6 M3
Grid 7	Grid 8	Grid 9
174.1 M3	191 3 M3	188 3 M3



0 dB = 196.0 V/m

Figure 15 HAC RF E-Field GSM 850 Channel 190

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HAC RF E-Field GSM 850 Low (Battery 1)

Date/Time: 4/23/2012 9:46:19 PM

Communication System: GSM 850; Frequency: 824.2 MHz; Duty Cycle: 1:8.3

Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 1000$ kg/m³

Ambient Temperature:22.3 $^{\circ}$ C Phantom section: RF Section

DASY5 Configuration:

Probe: ER3DV6 - SN2303; ConvF(1, 1, 1); Calibrated: 2/21/2012

Electronics: DAE4 Sn1317; Calibrated: 1/23/2012

Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA

Measurement SW: DASY5, V5.2 Build 162; SEMCAD X Version 14.0 Build 59

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device Low/Hearing Aid Compatibility

Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

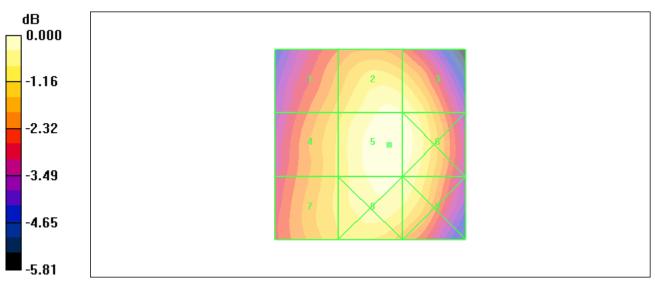
Maximum value of peak Total field = 182.8 V/m

Probe Modulation Factor = 2.81

Device Reference Point: 0.000, 0.000, -6.30 mm Reference Value = 82.5 V/m; Power Drift = -0.032 dB **Hearing Aid Near-Field Category: M3 (AWF -5 dB)**

Peak E-field in V/m

Grid 1	Grid 2	Grid 3
156.4 M3	177.6 M3	174.9 M3
Grid 4	Grid 5	Grid 6
161.6 M3	182.8 M3	180.5 M3
Grid 7	Grid 8	Grid 9
162.3 M3	177.7 M3	175.3 M3



0 dB = 182.8V/m

Figure 16 HAC RF E-Field GSM 850 Channel 128

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HAC RF E-Field GSM 850 Middle (Battery 2)

Date/Time: 4/23/2012 10:05:00 PM

Communication System: GSM 850; Frequency: 836.6 MHz; Duty Cycle: 1:8.3

Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 1000$ kg/m³

Ambient Temperature:22.3 $^{\circ}$ C Phantom section: RF Section

DASY5 Configuration:

Probe: ER3DV6 - SN2303; ConvF(1, 1, 1); Calibrated: 2/21/2012

Electronics: DAE4 Sn1317; Calibrated: 1/23/2012

Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA

Measurement SW: DASY5, V5.2 Build 162; SEMCAD X Version 14.0 Build 59

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device Middle/Hearing Aid

Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

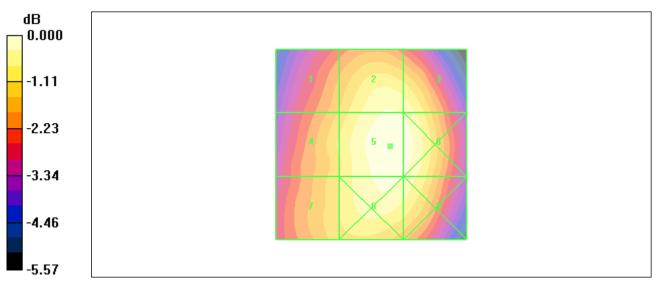
Maximum value of peak Total field = 188.6 V/m

Probe Modulation Factor = 2.81

Device Reference Point: 0.000, 0.000, -6.30 mm Reference Value = 84.6 V/m; Power Drift = -0.009 dB Hearing Aid Near-Field Category: M3 (AWF -5 dB)

Peak E-field in V/m

Grid 1	Grid 2	Grid 3
159.5 M3	181.5 M3	179.5 M3
Grid 4	Grid 5	Grid 6
166.9 M3	188.6 M3	185.8 M3
Grid 7	Grid 8	Grid 9
166.0 M3	183.3 M3	180.3 M3



0 dB = 188.6 V/m

Figure 17 HAC RF E-Field GSM 850 Channel 190

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HAC RF H-Field GSM 850 High (Battery 1)

Date/Time: 4/23/2012 6:40:08 PM

Communication System: GSM 850; Frequency: 848.8 MHz; Duty Cycle: 1:8.3

Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 1$ kg/m³

Ambient Temperature:22.3 $^{\circ}$ C Phantom section: RF Section

DASY5 Configuration:

Probe: H3DV6 - SN6138; ; Calibrated: 2/21/2012 Electronics: DAE4 Sn1317; Calibrated: 1/23/2012

Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA

Measurement SW: DASY5, V5.2 Build 162; SEMCAD X Version 14.0 Build 59

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device High/Hearing Aid

Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

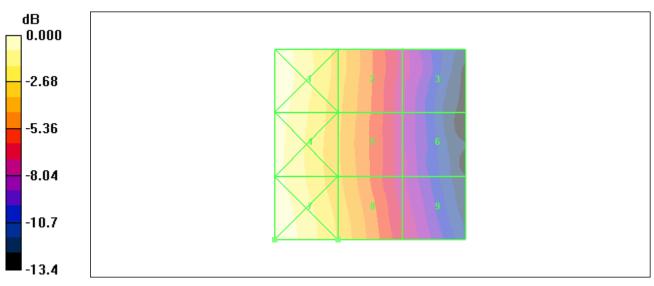
Maximum value of peak Total field = 0.275 A/m

Probe Modulation Factor = 2.75

Device Reference Point: 0.000, 0.000, -6.30 mm Reference Value = 0.077 A/m; Power Drift = -0.029 dB **Hearing Aid Near-Field Category: M4 (AWF -5 dB)**

Peak H-field in A/m

Grid 1	Grid 2	Grid 3
0.372 M4	0.266 M4	0.160 M4
Grid 4	Grid 5	Grid 6
0.363 M4	0.257 M4	0.156 M4
Grid 7	Grid 8	Grid 9
0.377 M4	0.275 M4	0.170 M4



0 dB = 0.377A/m

Figure 18 HAC RF H-Field GSM 850Channel 251

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HAC RF H-Field GSM 850 Middle (Battery 1)

Date/Time: 4/23/2012 6:45:08 PM

Communication System: GSM 850; Frequency: 836.6 MHz; Duty Cycle: 1:8.3

Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 1$ kg/m³

Ambient Temperature:22.3 $^{\circ}$ C Phantom section: RF Section

DASY5 Configuration:

Probe: H3DV6 - SN6138; ; Calibrated: 2/21/2012 Electronics: DAE4 Sn1317; Calibrated: 1/23/2012

Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA

Measurement SW: DASY5, V5.2 Build 162; SEMCAD X Version 14.0 Build 59

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device Middle/Hearing Aid

Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

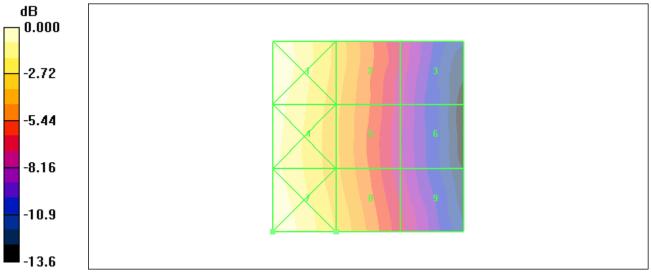
Maximum value of peak Total field = 0.272 A/m

Probe Modulation Factor = 2.75

Device Reference Point: 0.000, 0.000, -6.30 mm Reference Value = 0.076 A/m; Power Drift = 0.000 dB **Hearing Aid Near-Field Category: M4 (AWF -5 dB)**

Peak H-field in A/m

Grid 1	Grid 2	Grid 3
0.374 M4	0.266 M4	0.160 M4
Grid 4	Grid 5	Grid 6
0.360 M4	0.255 M4	0.152 M4
Grid 7		Grid 9



0 dB = 0.374A/m

Figure 19 HAC RF H-Field GSM 850 Channel 190

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HAC RF H-Field GSM 850 Low (Battery 1)

Date/Time: 4/23/2012 6:35:07 PM

Communication System: GSM 850; Frequency: 824.2 MHz; Duty Cycle: 1:8.3

Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 1$ kg/m³

Ambient Temperature:22.3 $^{\circ}$ C Phantom section: RF Section

DASY5 Configuration:

Probe: H3DV6 - SN6138; ; Calibrated: 2/21/2012 Electronics: DAE4 Sn1317; Calibrated: 1/23/2012

Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA

Measurement SW: DASY5, V5.2 Build 162; SEMCAD X Version 14.0 Build 59

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device Low/Hearing Aid Compatibility

Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

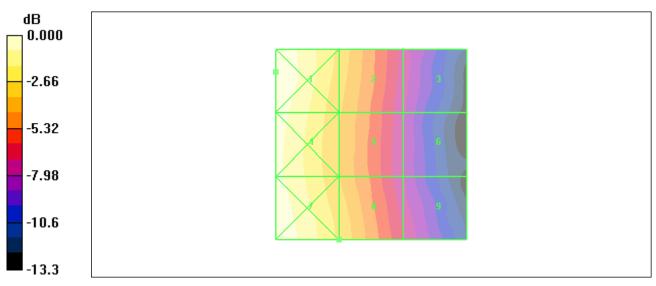
Maximum value of peak Total field = 0.258 A/m

Probe Modulation Factor = 2.75

Device Reference Point: 0.000, 0.000, -6.30 mm Reference Value = 0.072 A/m; Power Drift = -0.067 dB **Hearing Aid Near-Field Category: M4 (AWF -5 dB)**

Peak H-field in A/m

Grid 1	Grid 2	Grid 3
0.357 M4	0.257 M4	0.152 M4
Grid 4	Grid 5	Grid 6
0.345 M4	0.241 M4	0.145 M4
Grid 7	Grid 8	Grid 9
0.355 M4	0.258 M4	0.158 M4



0 dB = 0.357A/m

Figure 20 HAC RF H-Field GSM 850 Channel 128

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HAC RF H-Field GSM 850 High (Battery 2)

Date/Time: 4/23/2012 8:27:44 PM

Communication System: GSM 850; Frequency: 848.8 MHz; Duty Cycle: 1:8.3

Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 1$ kg/m³

Ambient Temperature:22.3 $^{\circ}$ C Phantom section: RF Section

DASY5 Configuration:

Probe: H3DV6 - SN6138; ; Calibrated: 2/21/2012 Electronics: DAE4 Sn1317; Calibrated: 1/23/2012

Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA

Measurement SW: DASY5, V5.2 Build 162; SEMCAD X Version 14.0 Build 59

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device High/Hearing Aid

Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

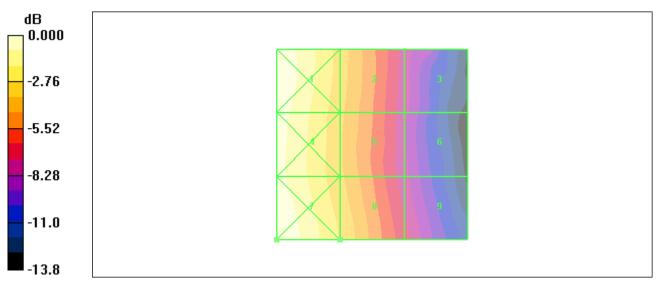
Maximum value of peak Total field = 0.272 A/m

Probe Modulation Factor = 2.75

Device Reference Point: 0.000, 0.000, -6.30 mm Reference Value = 0.076 A/m; Power Drift = -0.007 dB **Hearing Aid Near-Field Category: M4 (AWF -5 dB)**

Peak H-field in A/m

Grid 1	Grid 2	Grid 3
0.375 M4	0.263 M4	0.154 M4
Grid 4	Grid 5	Grid 6
0.360 M4	0.255 M4	0.152 M4
Grid 7	Grid 8	Grid 9
0.377 M4	0.272 M4	0.171 M4



0 dB = 0.377A/m

Figure 21 HAC RF H-Field GSM 850Channel 251

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HAC RF E-Field GSM 1900 High (Battery 1)

Date/Time: 4/23/2012 8:45:52 PM

Communication System: PCS 1900; Frequency: 1909.8 MHz; Duty Cycle: 1:8.3

Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 1000$ kg/m³

Ambient Temperature:22.3 $^{\circ}$ C Phantom section: RF Section

DASY5 Configuration:

Probe: ER3DV6 - SN2303; ConvF(1, 1, 1); Calibrated: 2/21/2012

Electronics: DAE4 Sn1317; Calibrated: 1/23/2012

Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA

Measurement SW: DASY5, V5.2 Build 162; SEMCAD X Version 14.0 Build 59

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device High/Hearing Aid Compatibility

Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

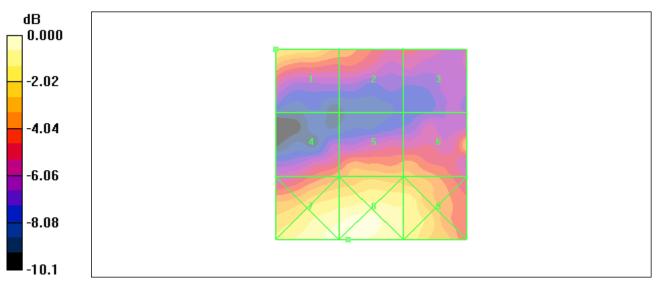
Maximum value of peak Total field = 71.1 V/m

Probe Modulation Factor = 2.84

Device Reference Point: 0.000, 0.000, -6.30 mm Reference Value = 17.2 V/m; Power Drift = 0.145 dB Hearing Aid Near-Field Category: M3 (AWF -5 dB)

Peak E-field in V/m

Grid 1	Grid 2	Grid 3
71.1 M3	58.0 M3	49.2 M3
Grid 4	Grid 5	Grid 6
57.9 M3	62.8 M3	61.1 M3
		61.1 M3 Grid 9



0 dB = 87.5 V/m

Figure 22 HAC RF E-Field GSM 1900 Channel 810

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HAC RF E-Field GSM 1900 Middle (Battery 1)

Date/Time: 4/23/2012 8:53:33 PM

Communication System: PCS 1900; Frequency: 1880 MHz; Duty Cycle: 1:8.3

Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 1000$ kg/m³

Ambient Temperature:22.3 $^{\circ}$ C Phantom section: RF Section

DASY5 Configuration:

Probe: ER3DV6 - SN2303; ConvF(1, 1, 1); Calibrated: 2/21/2012

Electronics: DAE4 Sn1317; Calibrated: 1/23/2012

Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA

Measurement SW: DASY5, V5.2 Build 162; SEMCAD X Version 14.0 Build 59

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device Middle/Hearing Aid

Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

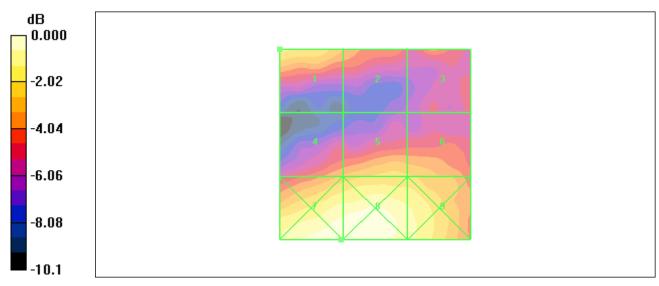
Maximum value of peak Total field = 74.4 V/m

Probe Modulation Factor = 2.84

Device Reference Point: 0.000, 0.000, -6.30 mm Reference Value = 19.2 V/m; Power Drift = 0.083 dB Hearing Aid Near-Field Category: M3 (AWF -5 dB)

Peak E-field in V/m

Grid 1	Grid 2	Grid 3
74.4 M3	62.5 M3	59.0 M3
Grid 4	Grid 5	Grid 6
63.4 M3	69.0 M3	68.3 M3
Grid 7	Grid 8	Grid 9



0 dB = 91.5V/m

Figure 23 HAC RF E-Field GSM 1900 Channel 661

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HAC RF E-Field GSM 1900 Low (Battery 1)

Date/Time: 4/23/2012 8:40:59 PM

Communication System: PCS 1900; Frequency: 1850.2 MHz; Duty Cycle: 1:8.3

Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 1000$ kg/m³

Ambient Temperature:22.3 $^{\circ}$ C Phantom section: RF Section

DASY5 Configuration:

Probe: ER3DV6 - SN2303; ConvF(1, 1, 1); Calibrated: 2/21/2012

Electronics: DAE4 Sn1317; Calibrated: 1/23/2012

Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA

Measurement SW: DASY5, V5.2 Build 162; SEMCAD X Version 14.0 Build 59

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device Low/Hearing Aid Compatibility

Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

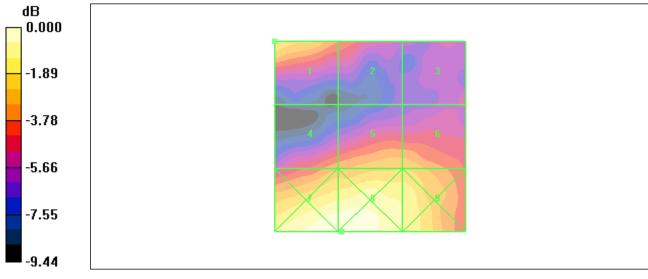
Maximum value of peak Total field = 79.0 V/m

Probe Modulation Factor = 2.84

Device Reference Point: 0.000, 0.000, -6.30 mm Reference Value = 22.0 V/m; Power Drift = -0.031 dB Hearing Aid Near-Field Category: M3 (AWF -5 dB)

Peak E-field in V/m

Grid 1	Grid 2	Grid 3
79.0 M3	64.8 M3	54.0 M3
Grid 4	Grid 5	Grid 6
68.4 M3	74.3 M3	74.3 M3
Grid 7	Grid 8	Grid 9
00 4 M2	90 2 M2	86.3 M2



0 dB = 99.2 V/m

Figure 24 HAC RF E-Field GSM 1900 Channel 512

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HAC RF E-Field GSM 1900 Low (Battery 2)

Date/Time: 4/23/2012 10:10:58 PM

Communication System: PCS 1900; Frequency: 1850.2 MHz; Duty Cycle: 1:8.3

Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 1000$ kg/m³

Ambient Temperature:22.3 $^{\circ}$ C Phantom section: RF Section

DASY5 Configuration:

Probe: ER3DV6 - SN2303; ConvF(1, 1, 1); Calibrated: 2/21/2012

Electronics: DAE4 Sn1317; Calibrated: 1/23/2012

Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA

Measurement SW: DASY5, V5.2 Build 162; SEMCAD X Version 14.0 Build 59

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device Low/Hearing Aid Compatibility

Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

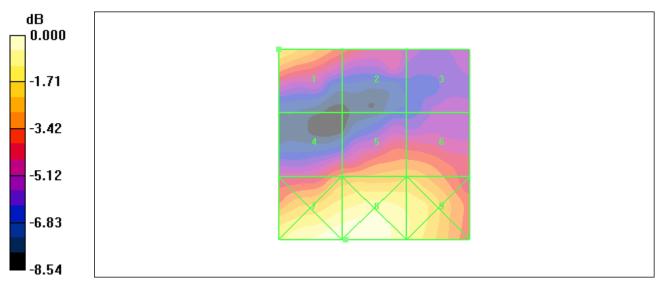
Maximum value of peak Total field = 76.2 V/m

Probe Modulation Factor = 2.84

Device Reference Point: 0.000, 0.000, -6.30 mm Reference Value = 20.6 V/m; Power Drift = 0.047 dB **Hearing Aid Near-Field Category: M3 (AWF -5 dB)**

Peak E-field in V/m

Grid 1	Grid 2	Grid 3
76.2 M3	61.1 M3	50.7 M3
Grid 4	Grid 5	Grid 6
65.2 M3	70.7 M3	70.7 M3
		70.7 M3 Grid 9



0 dB = 93.2V/m

Figure 25 HAC RF E-Field GSM 1900 Channel 512

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HAC RF H-Field GSM 1900 High (Battery 1)

Date/Time: 4/23/2012 6:57:51 PM

Communication System: PCS 1900; Frequency: 1909.8 MHz; Duty Cycle: 1:8.3

Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 1$ kg/m³

Ambient Temperature:22.3 $^{\circ}$ C Phantom section: RF Section

DASY5 Configuration:

Probe: H3DV6 - SN6138; ; Calibrated: 2/21/2012 Electronics: DAE4 Sn1317; Calibrated: 1/23/2012

Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA

Measurement SW: DASY5, V5.2 Build 162; SEMCAD X Version 14.0 Build 59

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device High/Hearing Aid

Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

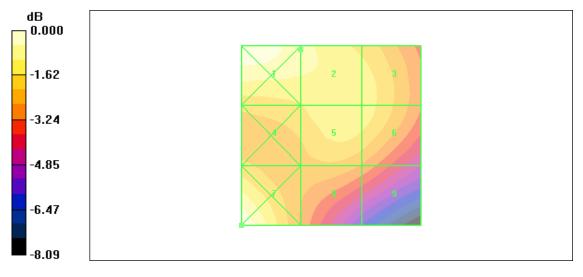
Maximum value of peak Total field = 0.203 A/m

Probe Modulation Factor = 2.84

Device Reference Point: 0.000, 0.000, -6.30 mm Reference Value = 0.077 A/m; Power Drift = 0.000 dB **Hearing Aid Near-Field Category: M3 (AWF -5 dB)**

Peak H-field in A/m

Grid 1	Grid 2	Grid 3
0.218 M3	0.203 M3	0.193 M3
Grid 4	Grid 5	Grid 6
0.185 M3	0.195 M3	0.193 M3
Grid 7	Grid 8	Grid 9
0.223 M3	0.172 M3	0.162 M3



0 dB = 0.223A/m

Figure 26 HAC RF H-Field GSM 1900 Channel 810

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HAC RF H-Field GSM 1900 Middle (Battery 1)

Date/Time: 4/23/2012 7:02:43 PM

Communication System: PCS 1900; Frequency: 1880 MHz; Duty Cycle: 1:8.3

Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 1$ kg/m³

Ambient Temperature:22.3 $^{\circ}$ C Phantom section: RF Section

DASY5 Configuration:

Probe: H3DV6 - SN6138; ; Calibrated: 2/21/2012 Electronics: DAE4 Sn1317; Calibrated: 1/23/2012

Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA

Measurement SW: DASY5, V5.2 Build 162; SEMCAD X Version 14.0 Build 59

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device Middle/Hearing Aid

Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

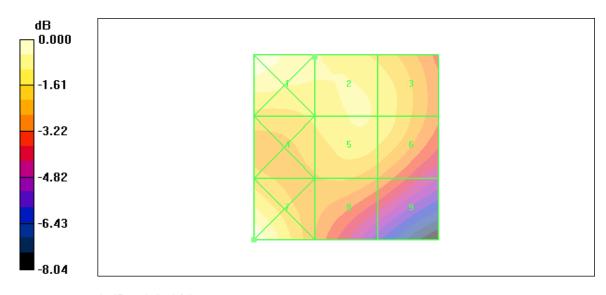
Maximum value of peak Total field = 0.217 A/m

Probe Modulation Factor = 2.84

Device Reference Point: 0.000, 0.000, -6.30 mm Reference Value = 0.084 A/m; Power Drift = -0.021 dB **Hearing Aid Near-Field Category: M3 (AWF -5 dB)**

Peak H-field in A/m

Grid 1	Grid 2	Grid 3
0.236 M3	0.217 M3	0.212 M3
Grid 4	Grid 5	Grid 6
0.204 M3	0.215 M3	0.212 M3
Grid 7	Grid 8	Grid 9
0.242 M3	0.190 M3	0.178 M3



0 dB = 0.242A/m

Figure 27 HAC RF H-Field GSM 1900 Channel 661

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HAC RF H-Field GSM 1900 Low (Battery 1)

Date/Time: 4/23/2012 6:52:57 PM

Communication System: PCS 1900; Frequency: 1850.2 MHz; Duty Cycle: 1:8.3

Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 1$ kg/m³

Ambient Temperature:22.3 $^{\circ}$ C Phantom section: RF Section

DASY5 Configuration:

Probe: H3DV6 - SN6138; ; Calibrated: 2/21/2012 Electronics: DAE4 Sn1317; Calibrated: 1/23/2012

Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA

Measurement SW: DASY5, V5.2 Build 162; SEMCAD X Version 14.0 Build 59

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device Low/Hearing Aid Compatibility

Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

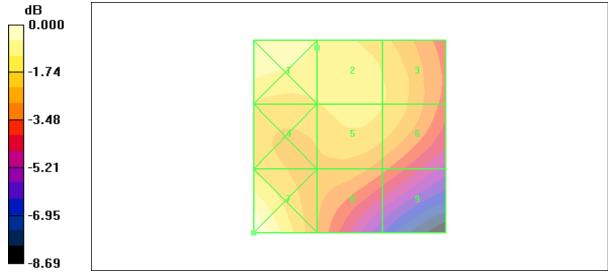
Maximum value of peak Total field = 0.228 A/m

Probe Modulation Factor = 2.84

Device Reference Point: 0.000, 0.000, -6.30 mm Reference Value = 0.086 A/m; Power Drift = -0.063 dB **Hearing Aid Near-Field Category: M3 (AWF -5 dB)**

Peak H-field in A/m

Grid 1	Grid 2	Grid 3
0.247 M3	0.228 M3	0.217 M3
Grid 4	Grid 5	Grid 6
0.215 M3	0.222 M3	0.216 M3
Grid 7	Grid 8	Grid 9
0.263 M2	0.198 M3	0.180 M3



0 dB = 0.263A/m

Figure 28 HAC RF H-Field GSM 1900 Channel 512

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HAC RF H-Field GSM 1900 Low (Battery 2)

Date/Time: 4/23/2012 8:21:51 PM

Communication System: PCS 1900; Frequency: 1850.2 MHz; Duty Cycle: 1:8.3

Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 1$ kg/m³

Ambient Temperature:22.3 ℃ Phantom section: RF Section

DASY5 Configuration:

Probe: H3DV6 - SN6138; ; Calibrated: 2/21/2012 Electronics: DAE4 Sn1317; Calibrated: 1/23/2012

Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA

Measurement SW: DASY5, V5.2 Build 162; SEMCAD X Version 14.0 Build 59

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device Low/Hearing Aid Compatibility

Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

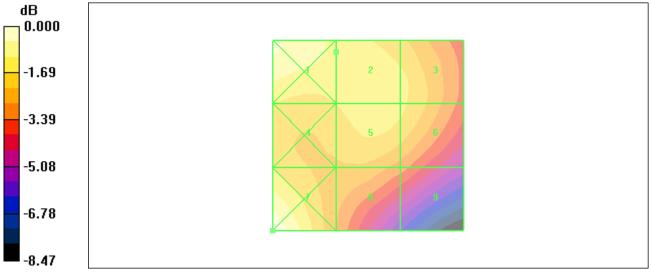
Maximum value of peak Total field = 0.233 A/m

Probe Modulation Factor = 2.84

Device Reference Point: 0.000, 0.000, -6.30 mm Reference Value = 0.091 A/m; Power Drift = -0.017 dB **Hearing Aid Near-Field Category: M3 (AWF -5 dB)**

Peak H-field in A/m

Grid 1	Grid 2	Grid 3
0.255 M2	0.233 M3	0.225 M3
Grid 4	Grid 5	Grid 6
0.222 M3	0.230 M3	0.225 M3
Grid 7	Grid 8	Grid 9
0.269 M2	0.206 M3	0.188 M3



0 dB = 0.269A/m

Figure 29 HAC RF H-Field GSM 1900 Channel 512

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HAC RF E-Field WCDMA Band II High (Battery 1)

Date/Time: 8/19/2012 12:17:03 PM

Communication System: WCDMA; Frequency: 1907.6 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 1000$ kg/m³

Ambient Temperature:22.3 $^{\circ}$ C Phantom section: RF Section

DASY5 Configuration:

Probe: ER3DV6 - SN2303; ConvF(1, 1, 1); Calibrated: 2/21/2012

Electronics: DAE4 Sn1317; Calibrated: 1/23/2012

Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA

Measurement SW: DASY5, V5.2 Build 162; SEMCAD X Version 14.0 Build 59

one touch 871A WCDMA Band II HAC RF E-Field/E Scan - ER3D - 2007: 15 mm from Probe Center to the Device High/Hearing Aid Compatibility Test (101x101x1): Measurement grid:

dx=5mm, dy=5mm

Maximum value of peak Total field = 37.5 V/m

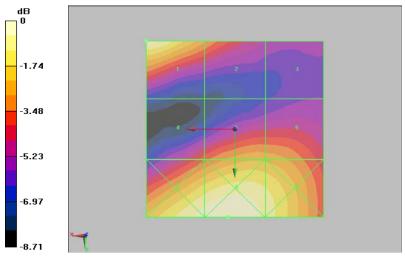
Probe Modulation Factor = 1.03

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 22.8 V/m; Power Drift = -0.131 dB Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1	Grid 2	Grid 3
37.5 M4	28 M4	21.2 M 4
Grid 4	Grid 5	Grid 6
25 2 MA	29.3 M4	20 M4
25.3 WI4	29.3 IVI4	29 IVI4
	Grid 8	Grid 9



0 dB = 38.6 V/m

Figure 30 HAC RF E-Field WCDMA Band II Channel 9538

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HAC RF E-Field WCDMA Band II Middle (Battery 1)

Date/Time: 8/19/2012 11:59:32 AM

Communication System: WCDMA; Frequency: 1880 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 1000$ kg/m³

Ambient Temperature:22.3 $^{\circ}$ C Phantom section: RF Section

DASY5 Configuration:

Probe: ER3DV6 - SN2303; ConvF(1, 1, 1); Calibrated: 2/21/2012

Electronics: DAE4 Sn1317; Calibrated: 1/23/2012

Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA

Measurement SW: DASY5, V5.2 Build 162; SEMCAD X Version 14.0 Build 59

one touch 871A WCDMA Band II HAC RF E-Field/E Scan - ER3D - 2007: 15 mm from Probe Center to the Device Middle/Hearing Aid Compatibility Test (101x101x1): Measurement grid:

dx=5mm, dy=5mm

Maximum value of peak Total field = 37.8 V/m

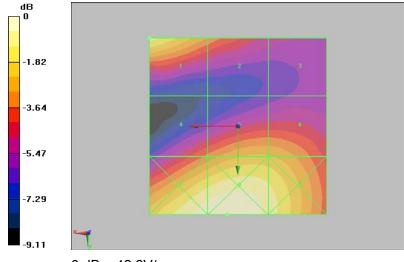
Probe Modulation Factor = 1.03

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 25.9 V/m; Power Drift = -0.057 dB Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1	Grid 2	Grid 3
37.8 M4	29.8 M 4	23.8 M4
Grid 4	Grid 5	Grid 6
28.4 M4	32.4 M4	32.1 M4
		32.1 M4 Grid 9



0 dB = 42.2V/m

Figure 31 HAC RF E-Field WCDMA Band II Channel 9400

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HAC RF E-Field WCDMA Band II Low (Battery 1)

Date/Time: 8/19/2012 12:22:54 PM

Communication System: WCDMA; Frequency: 1852.4 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 1000$ kg/m³

Ambient Temperature:22.3 $^{\circ}$ C Phantom section: RF Section

DASY5 Configuration:

Probe: ER3DV6 - SN2303; ConvF(1, 1, 1); Calibrated: 2/21/2012

Electronics: DAE4 Sn1317; Calibrated: 1/23/2012

Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA

Measurement SW: DASY5, V5.2 Build 162; SEMCAD X Version 14.0 Build 59

one touch 871A WCDMA Band II HAC RF E-Field/E Scan - ER3D - 2007: 15 mm from Probe Center to the Device Low/Hearing Aid Compatibility Test (101x101x1): Measurement grid:

dx=5mm, dy=5mm

Maximum value of peak Total field = 30.7 V/m

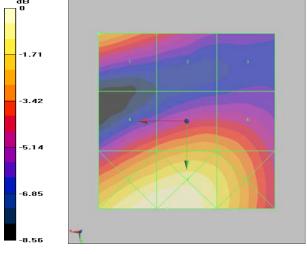
Probe Modulation Factor = 1.03

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 26.2 V/m; Power Drift = -0.002dB Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1	Grid 2	Grid 3
30.7 M4	25.3 M4	20.5 M4
Grid 4	Grid 5	Grid 6
27.7 M4	30.2 M4	29.7 M4
	30.2 M4 Grid 8	



0 dB = 39.3V/m

Figure 32 HAC RF E-Field WCDMA Band II Channel 9262

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HAC RF E-Field WCDMA Band II Middle (Battery 2)

Date/Time: 8/19/2012 12:36:36 PM

Communication System: WCDMA; Frequency: 1880 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 1000$ kg/m³

Ambient Temperature:22.3 $^{\circ}$ C Phantom section: RF Section

DASY5 Configuration:

Probe: ER3DV6 - SN2303; ConvF(1, 1, 1); Calibrated: 2/21/2012

Electronics: DAE4 Sn1317; Calibrated: 1/23/2012

Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA

Measurement SW: DASY5, V5.2 Build 162; SEMCAD X Version 14.0 Build 59

one touch 871A WCDMA Band II HAC RF E-Field With Battery C1/E Scan - ER3D - 2007: 15 mm from Probe Center to the Device Middle/Hearing Aid Compatibility Test (101x101x1):

Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 38.1 V/m

Probe Modulation Factor = 1.03

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 25.7 V/m; Power Drift = -0.072 dB Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1	Grid 2	Grid 3
38.1 M4	30.2 M4	23.9 M4
Grid 4	Grid 5	Grid 6
<i></i>		
28.2 M4	32.1 M4	31.9 M4
	32.1 M4 Grid 8	

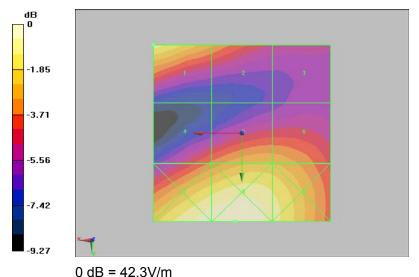


Figure 33 HAC RF E-Field WCDMA Band II Channel 9400

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HAC RF H-Field WCDMA Band II High (Battery 1)

Date/Time: 8/19/2012 1:02:28 PM

Communication System: WCDMA; Frequency: 1907.6 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 1$ kg/m³

Ambient Temperature:22.3 $^{\circ}$ C Phantom section: RF Section

DASY5 Configuration:

Probe: H3DV6 - SN6138; ; Calibrated: 2/21/2012 Electronics: DAE4 Sn1317; Calibrated: 1/23/2012

Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA

Measurement SW: DASY5, V5.2 Build 162; SEMCAD X Version 14.0 Build 59

One touch 871A WCDMA Band II HAC RF H-Field/H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device High/Hearing Aid Compatibility Test (101x101x1): Measurement grid:

dx=5mm, dy=5mm

Maximum value of peak Total field = 0.095 A/m

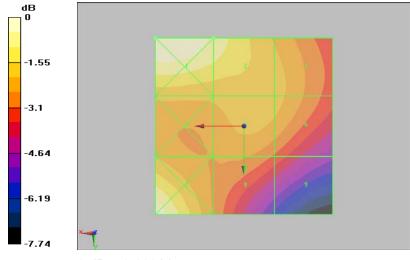
Probe Modulation Factor = 1.01

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 0.093 A/m; Power Drift = 0.017 dB Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

Grid 1	Grid 2	Grid 3
0.103 M4	0.095 M4	0.084 M4
Grid 4	Grid 5	Grid 6
0.083 M4	0 085 M4	0 083 M4
	0.005 IVI -	0.005 IVI T
		Grid 9



0 dB = 0.103A/m

Figure 34 HAC RF H-Field WCDMA Band II Channel 9538

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HAC RF H-Field WCDMA Band II Middle (Battery 1)

Date/Time: 8/19/2012 12:50:30 PM

Communication System: WCDMA; Frequency: 1880 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 1$ kg/m³

Ambient Temperature:22.3 $^{\circ}$ C Phantom section: RF Section

DASY5 Configuration:

Probe: H3DV6 - SN6138; ; Calibrated: 2/21/2012 Electronics: DAE4 Sn1317; Calibrated: 1/23/2012

Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA

Measurement SW: DASY5, V5.2 Build 162; SEMCAD X Version 14.0 Build 59

One touch 871A WCDMA Band II HAC RF H-Field/H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device Middle/Hearing Aid Compatibility Test (101x101x1): Measurement grid:

dx=5mm, dy=5mm

Maximum value of peak Total field = 0.106 A/m

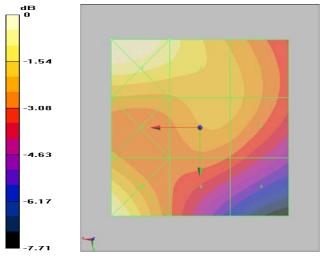
Probe Modulation Factor = 1.01

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 0.103 A/m; Power Drift = -0.019 dB Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

Grid 1	Grid 2	Grid 3
0.115 M4	0.106 M4	0.094 M4
Grid 4	Grid 5	Grid 6
0.091 M4	0.095 M4	0.093 M4
Grid 7	Grid 8	Grid 9
Ond 7	Gilu o	Giiu 9



0 dB = 0.115A/m

Figure 35 HAC RF H-Field WCDMA Band II Channel 9400

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HAC RF H-Field WCDMA Band II Low (Battery 1)

Date/Time: 8/19/2012 12:56:18 PM

Communication System: WCDMA; Frequency: 1852.4 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 1$ kg/m³

Ambient Temperature:22.3 $^{\circ}$ C Phantom section: RF Section

DASY5 Configuration:

Probe: H3DV6 - SN6138; ; Calibrated: 2/21/2012 Electronics: DAE4 Sn1317; Calibrated: 1/23/2012

Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA

Measurement SW: DASY5, V5.2 Build 162; SEMCAD X Version 14.0 Build 59

One touch 871A WCDMA Band II HAC RF H-Field/H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device Low/Hearing Aid Compatibility Test (101x101x1): Measurement grid:

dx=5mm, dy=5mm

Maximum value of peak Total field = 0.089 A/m

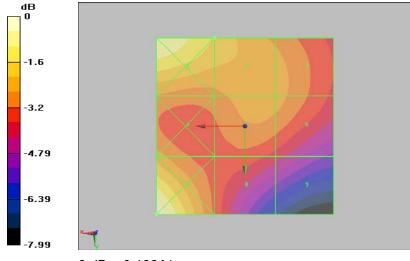
Probe Modulation Factor = 1.01

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 0.091 A/m; Power Drift = -0.002 dB Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

Grid 1	Grid 2	Grid 3
0.102 M4	0.089 M4	0.082 M4
Grid 4	Grid 5	Grid 6
0.082 M4	0 083 M4	0 082 M4
	0.000 IVI-	0.002 IVI-
		Grid 9



0 dB = 0.108A/m

Figure 36 HAC RF H-Field WCDMA Band II Channel 9262

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HAC RF H-Field WCDMA Band II Middle (Battery 2)

Date/Time: 8/19/2012 1:12:15 PM

Communication System: WCDMA; Frequency: 1880 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 1$ kg/m³

Ambient Temperature:22.3 $^{\circ}$ C Phantom section: RF Section

DASY5 Configuration:

Probe: H3DV6 - SN6138; ; Calibrated: 2/21/2012 Electronics: DAE4 Sn1317; Calibrated: 1/23/2012

Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA

Measurement SW: DASY5, V5.2 Build 162; SEMCAD X Version 14.0 Build 59

One touch 871A WCDMA Band II HAC RF H-Field/H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device Middle/Hearing Aid Compatibility Test (101x101x1): Measurement grid:

dx=5mm, dy=5mm

Maximum value of peak Total field = 0.105 A/m

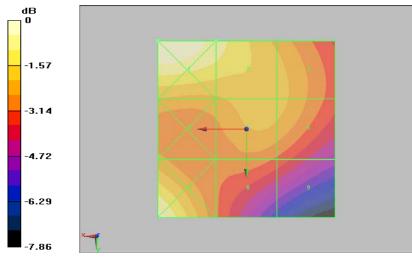
Probe Modulation Factor = 1.01

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 0.102 A/m; Power Drift = -0.003 dB Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

Grid 1	Grid 2	Grid 3
0.115 M4	0.105 M4	0.093 M4
Grid 4	Grid 5	Grid 6
0.090 M4	0.094 M4	0.093 M4
Grid 7	Grid 8	Grid 9
0 112 MA	0 083 M4	0.079 M4



0 dB = 0.115A/m

Figure 37 HAC RF H-Field WCDMA Band II Channel 9400

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HAC RF E-Field WCDMA Band V High (Battery 1)

Date/Time: 4/23/2012 9:35:45 PM

Communication System: WCDMA Band V; Frequency: 846.6 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 1000$ kg/m³

Ambient Temperature:22.3 $^{\circ}$ C Phantom section: RF Section

DASY5 Configuration:

Probe: ER3DV6 - SN2303; ConvF(1, 1, 1); Calibrated: 2/21/2012

Electronics: DAE4 Sn1317; Calibrated: 1/23/2012

Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA

Measurement SW: DASY5, V5.2 Build 162; SEMCAD X Version 14.0 Build 59

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device High/Hearing Aid Compatibility

Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

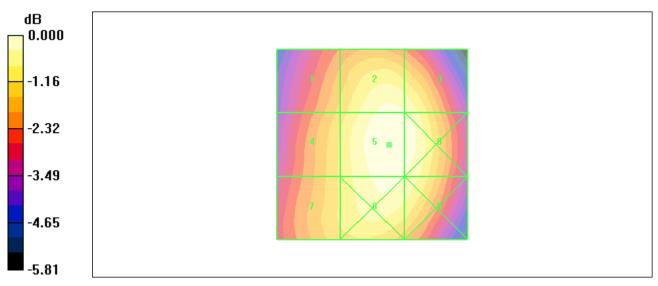
Maximum value of peak Total field = 77.4 V/m

Probe Modulation Factor = 1.03

Device Reference Point: 0.000, 0.000, -6.30 mm Reference Value = 95.7 V/m; Power Drift = -0.021 dB Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1	Grid 2	Grid 3
65.9 M4	75.3 M4	74.3 M4
Grid 4	Grid 5	Grid 6
68.2 M 4	77.4 M 4	76.6 M4
Grid 7	Grid 8	Grid 9
68.1 M4	75.5 M4	74.2 M4



0 dB = 77.4 V/m

Figure 38 HAC RF E-Field WCDMA Band V Channel 4233

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HAC RF E-Field WCDMA Band V Middle (Battery 1)

Date/Time: 4/23/2012 9:30:51 PM

Communication System: WCDMA Band V; Frequency: 836.6 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 1000$ kg/m³

Ambient Temperature:22.3 $^{\circ}$ C Phantom section: RF Section

DASY5 Configuration:

Probe: ER3DV6 - SN2303; ConvF(1, 1, 1); Calibrated: 2/21/2012

Electronics: DAE4 Sn1317; Calibrated: 1/23/2012

Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA

Measurement SW: DASY5, V5.2 Build 162; SEMCAD X Version 14.0 Build 59

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device Middle/Hearing Aid

Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

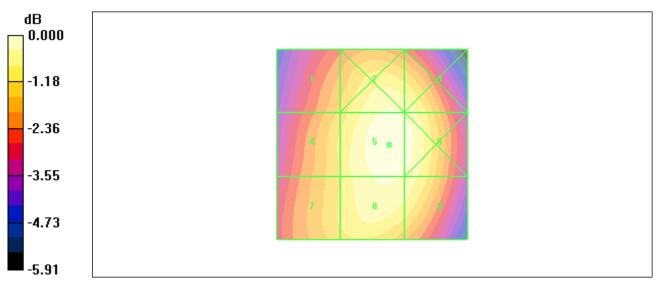
Maximum value of peak Total field = 71.3 V/m

Probe Modulation Factor = 1.03

Device Reference Point: 0.000, 0.000, -6.30 mm Reference Value = 87.4 V/m; Power Drift = -0.034 dB Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1	Grid 2	Grid 3
60.3 M4	68.8 M 4	67.7 M4
Grid 4	Grid 5	Grid 6
62.9 M4	71.3 M 4	70.0 M4
Grid 7	Grid 8	Grid 9
62.7 M4	68.7 M4	67.7 M4



0 dB = 71.3V/m

Figure 39 HAC RF E-Field WCDMA Band V Channel 4183

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HAC RF E-Field WCDMA Band V Low (Battery 1)

Date/Time: 4/23/2012 9:40:42 PM

Communication System: WCDMA Band V; Frequency: 826.4 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 1000$ kg/m³

Ambient Temperature:22.3 $^{\circ}$ C Phantom section: RF Section

DASY5 Configuration:

Probe: ER3DV6 - SN2303; ConvF(1, 1, 1); Calibrated: 2/21/2012

Electronics: DAE4 Sn1317; Calibrated: 1/23/2012

Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA

Measurement SW: DASY5, V5.2 Build 162; SEMCAD X Version 14.0 Build 59

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device Low/Hearing Aid Compatibility

Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

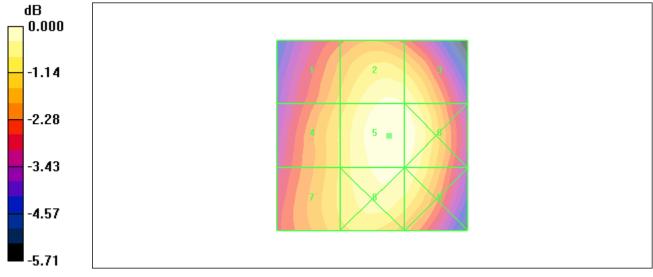
Maximum value of peak Total field = 73.3 V/m

Probe Modulation Factor = 1.03

Device Reference Point: 0.000, 0.000, -6.30 mm Reference Value = 90.6 V/m; Power Drift = -0.012 dB Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1	Grid 2	Grid 3
62.6 M4	71.1 M 4	70.1 M4
Grid 4	Grid 5	Grid 6
64.8 M 4	73.3 M 4	72.5 M 4
Grid 7	Grid 8	Grid 9
64.9 M4	71.3 M4	70.2 M4



0 dB = 73.3V/m

Figure 40 HAC RF E-Field WCDMA Band V Channel 4132

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HAC RF E-Field WCDMA Band V High (Battery 2)

Date/Time: 4/23/2012 9:59:26 PM

Communication System: WCDMA Band V; Frequency: 846.6 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 1000$ kg/m³

Ambient Temperature:22.3 $^{\circ}$ C Phantom section: RF Section

DASY5 Configuration:

Probe: ER3DV6 - SN2303; ConvF(1, 1, 1); Calibrated: 2/21/2012

Electronics: DAE4 Sn1317; Calibrated: 1/23/2012

Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA

Measurement SW: DASY5, V5.2 Build 162; SEMCAD X Version 14.0 Build 59

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device High/Hearing Aid Compatibility

Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

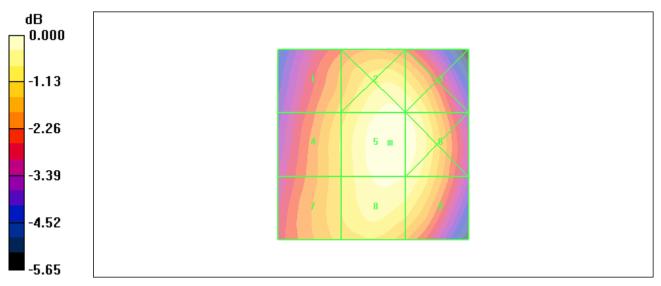
Maximum value of peak Total field = 77.3 V/m

Probe Modulation Factor = 1.03

Device Reference Point: 0.000, 0.000, -6.30 mm Reference Value = 95.4 V/m; Power Drift = -0.003 dB Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1	Grid 2	Grid 3
66.2 M4	75.2 M 4	74.2 M 4
Grid 4	Grid 5	Grid 6
68.4 M4	77.3 M 4	76.5 M4
Grid 7	Grid 8	Grid 9
68.0 M4	75.0 M4	74.0 M4



0 dB = 77.3V/m

Figure 41 HAC RF E-Field WCDMA Band V Channel 4233

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HAC RF H-Field WCDMA Band V High (Battery 1)

Date/Time: 4/23/2012 7:40:42 PM

Communication System: WCDMA Band V; Frequency: 846.6 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 1$ kg/m³

Ambient Temperature:22.3 $^{\circ}$ C Phantom section: RF Section

DASY5 Configuration:

Probe: H3DV6 - SN6138; ; Calibrated: 2/21/2012 Electronics: DAE4 Sn1317; Calibrated: 1/23/2012

Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA

Measurement SW: DASY5, V5.2 Build 162; SEMCAD X Version 14.0 Build 59

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device High/Hearing Aid

Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

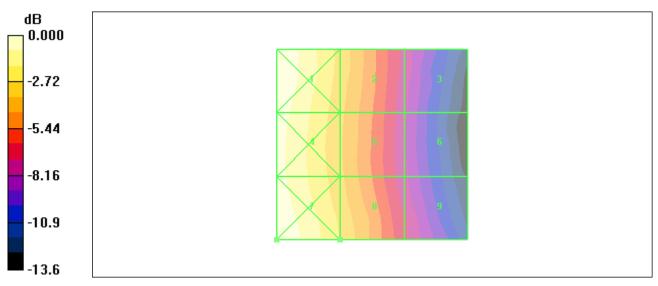
Maximum value of peak Total field = 0.107 A/m

Probe Modulation Factor = 1.01

Device Reference Point: 0.000, 0.000, -6.30 mm Reference Value = 0.081 A/m; Power Drift = 0.031 dB **Hearing Aid Near-Field Category: M4 (AWF 0 dB)**

Peak H-field in A/m

Grid 1	Grid 2	Grid 3		
0.146 M4	0.104 M4	0.062 M4		
Grid 4	Grid 5	Grid 6		
	<mark>0.100 M4</mark> 0.059 M ⁴			
0.141 M4	0.100 M4	0.059 M4		
		0.059 M4 Grid 9		



0 dB = 0.147A/m

Figure 42 HAC RF H-Field WCDMA Band V Channel 4233

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HAC RF H-Field WCDMA Band V Middle (Battery 1)

Date/Time: 4/23/2012 7:35:51 PM

Communication System: WCDMA Band V; Frequency: 836.6 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 1$ kg/m³

Ambient Temperature:22.3 $^{\circ}$ C Phantom section: RF Section

DASY5 Configuration:

Probe: H3DV6 - SN6138; ; Calibrated: 2/21/2012 Electronics: DAE4 Sn1317; Calibrated: 1/23/2012

Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA

Measurement SW: DASY5, V5.2 Build 162; SEMCAD X Version 14.0 Build 59

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device Middle/Hearing Aid

Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.098 A/m

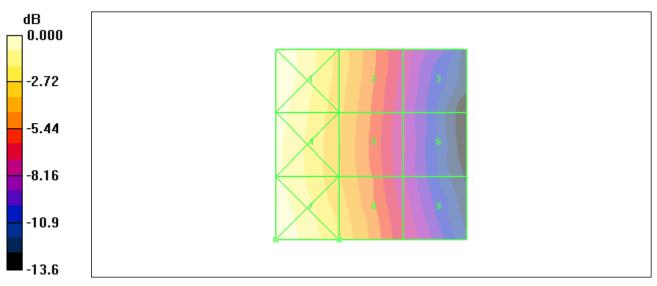
Probe Modulation Factor = 1.01

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.074 A/m; Power Drift = -0.051 dB **Hearing Aid Near-Field Category: M4 (AWF 0 dB)**

Peak H-field in A/m

Grid 1	Grid 2	Grid 3	
0.134 M4	0.095 M4	0.057 M4	
Grid 4	Grid 5	Grid 6	
0.128 M4	0.092 M4	0.054 M4	
Grid 7	Grid 8	Grid 9	
0.135 M4	0.098 M4	0.059 M4	



0 dB = 0.135A/m

Figure 43 HAC RF H-Field WCDMA Band V Channel 4183

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HAC RF H-Field WCDMA Band V Low (Battery 1)

Date/Time: 4/23/2012 7:45:34 PM

Communication System: WCDMA Band V; Frequency: 826.4 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 1$ kg/m³

Ambient Temperature:22.3 $^{\circ}$ C Phantom section: RF Section

DASY5 Configuration:

Probe: H3DV6 - SN6138; ; Calibrated: 2/21/2012 Electronics: DAE4 Sn1317; Calibrated: 1/23/2012

Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA

Measurement SW: DASY5, V5.2 Build 162; SEMCAD X Version 14.0 Build 59

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device Low/Hearing Aid Compatibility

Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.100 A/m

Probe Modulation Factor = 1.01

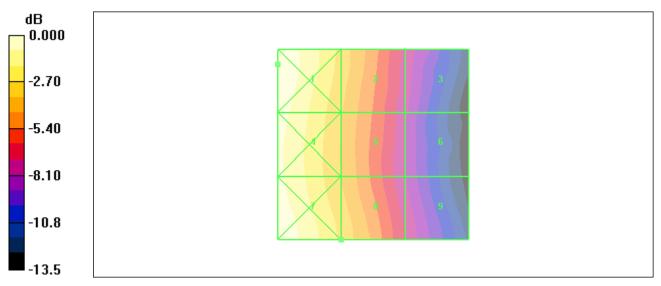
Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.076 A/m; Power Drift = -0.007 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

Grid 1	Grid 2	Grid 3	
0.139 M4	0.098 M4	0.059 M4	
Grid 4	Grid 5	Grid 6	
0.132 M4	0.093 M4	0.056 M4	
Grid 7	Grid 8	Grid 9	
0.138 M4	0.100 M4	0.061 M4	



0 dB = 0.139A/m

Figure 44 HAC RF H-Field WCDMA Band V Channel 4132

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HAC RF H-Field WCDMA Band V High (Battery 2)

Date/Time: 4/23/2012 8:07:43 PM

Communication System: WCDMA Band V; Frequency: 846.6 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 1$ kg/m³

Ambient Temperature:22.3 $^{\circ}$ C Phantom section: RF Section

DASY5 Configuration:

Probe: H3DV6 - SN6138; ; Calibrated: 2/21/2012 Electronics: DAE4 Sn1317; Calibrated: 1/23/2012

Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA

Measurement SW: DASY5, V5.2 Build 162; SEMCAD X Version 14.0 Build 59

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device High/Hearing Aid

Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

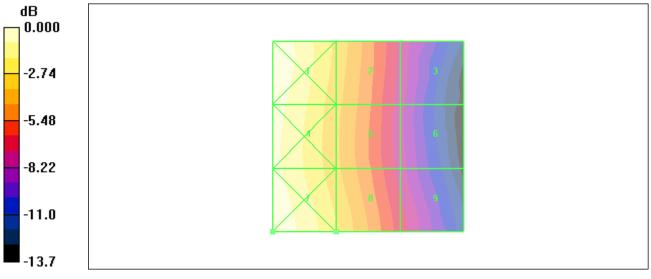
Maximum value of peak Total field = 0.111 A/m

Probe Modulation Factor = 1.01

Device Reference Point: 0.000, 0.000, -6.30 mm Reference Value = 0.084 A/m; Power Drift = -0.020 dB **Hearing Aid Near-Field Category: M4 (AWF 0 dB)**

Peak H-field in A/m

Grid 1	Grid 2	Grid 3		
0.150 M4	0.107 M4	0.064 M4		
Grid 4	Grid 5	Grid 6		
0.144 M4	0.103 M4	0.062 M4		
Grid 7	Grid 8	Grid 9		
0.151 M4	0.111 M4	0.069 M4		



0 dB = 0.151A/m

Figure 45 HAC RF H-Field WCDMA Band V Channel 4233

ANNEX C: E-Probe Calibration Certificate

Calibration Laboratory of Schmid & Partner Engineering AG Zeughausstrasse 43, 8004 Zurich, Switzerland





Schweizerischer Kalibrierdienst S Service suisse d'étalonnage Servizio svizzero di taratura

Swiss Calibration Service

Accredited by the Swiss Accreditation Service (SAS) The Swiss Accreditation Service is one of the signatories to the EA Multilateral Agreement for the recognition of calibration certificates

TA Shanghai (Auden)

Certificate No: ER3-2303 Feb12

Accreditation No.: SCS 108

C

CALIBRATION CERTIFICATE

Object

ER3DV6 - SN:2303

Calibration procedure(s)

QA CAL-02.v6, QA CAL-25.v4

Calibration procedure for E-field probes optimized for close near field

evaluations in air

Calibration date:

February 21, 2012

This calibration certificate documents the traceability to national standards, which realize the physical units of measurements (SI): The measurements and the uncertainties with confidence probability are given on the following pages and are part of the certificate.

All calibrations have been conducted in the closed laboratory facility: environment temperature (22 ± 3)°C and humidity < 70%.

Calibration Equipment used (M&TE critical for calibration)

Primary Standards	ID	Cal Date (Certificate No.)	Scheduled Calibration	
Power meter E4419B	GB41293874	31-Mar-11 (No. 217-01372)	Apr-12	
Power sensor E4412A	MY41496087	31-Mar-11 (No. 217-01372)	Apr-12	
Reference 3 dB Attenuator	SN: S5054 (3c)	29-Mar-11 (No. 217-01369)	Apr-12	
Reference 20 dB Attenuator	SN: S5086 (20b)	29-Mar-11 (No. 217-01367)	Apr-12	
Reference 30 dB Attenuator	SN: S5129 (30b)	29-Mar-11 (No. 217-01370)	Apr-12	
Reference Probe ER30V6	SN: 2328	11-Oct-11 (No. ER3-2328_Oct11)	Oct-12	
DAE4	SN: 789	30-Jan-12 (No. DAE4-789_Jan12)	Jan-13 -	
Secondary Standards	ID	Check Date (in house)	Scheduled Check	
RF generator HP 8648C	US3642U01700 *	4-Aug-99 (in house check Apr-11)	In house check: Apr-13	
Network Analyzer HP 8753E	US37390585	18-Oct-01 (in house check Oct-11)	In house check: Oct-12	

Name Function Calibrated by Claudio Leubler Laboratory Technician Katja Pokovic Technical Manager Approved by:

ssued: February 22, 2012

This calibration certificate shall not be reproduced except in full without written approval of the laboratory.

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Calibration Laboratory of Schmid & Partner Engineering AG Zeughausstrasse 43, 8004 Zurich, Switzerland





S Schweizerischer Kalibrierdienst
C Service suisse d'étalonnage
Servizio svizzero di taratura
Swiss Calibration Service

Accreditation No.: SCS 108

Accredited by the Swiss Accreditation Service (SAS)

The Swiss Accreditation Service is one of the signatories to the EA Multilateral Agreement for the recognition of calibration certificates

Glossary:

NORMx,y,z

sensitivity in free space

DCP

diode compression point crest factor (1/duty_cycle) of the RF signal

CF A, B, C

modulation dependent linearization parameters

Polarization o

o rotation around probe axis

Polarization 9

9 rotation around an axis that is in the plane normal to probe axis (at measurement center),

i.e., 9 = 0 is normal to probe axis

Connector Angle

information used in DASY system to align probe sensor X to the robot coordinate system

Calibration is Performed According to the Following Standards:

 a) IEEE Std 1309-2005, * IEEE Standard for calibration of electromagnetic field sensors and probes, excluding antennas, from 9 kHz to 40 GHz", December 2005.

Methods Applied and Interpretation of Parameters:

- NORMx, y, z: Assessed for E-field polarization 9 = 0 for XY sensors and 9 = 90 for Z sensor (f ≤ 900 MHz in TEM-cell; f > 1800 MHz: R22 waveguide).
- NORM(f)x,y,z = NORMx,y,z * frequency_response (see Frequency Response Chart).
- DCPx,y,z: DCP are numerical linearization parameters assessed based on the data of power sweep with CW signal (no uncertainty required). DCP does not depend on frequency nor media.
- PAR: PAR is the Peak to Average Ratio that is not calibrated but determined based on the signal characteristics
- Ax,y,z; Bx,y,z; Cx,y,z, VRx,y,z: A, B, C are numerical linearization parameters assessed based on the data of power sweep for specific modulation signal. The parameters do not depend on frequency nor media. VR is the maximum calibration range expressed in RMS voltage across the diode.
- Spherical isotropy (3D deviation from isotropy): in a locally homogeneous field realized using an open wavenuide setup.
- Sensor Offset: The sensor offset corresponds to the offset of virtual measurement center from the probe-tip (on probe axis). No tolerance required.
- Connector Angle: The angle is assessed using the information gained by determining the NORMx (no uncertainty required).

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ER3DV6 - SN:2303

February 21, 2012

Probe ER3DV6

SN:2303

Manufactured:

November 6, 2002

Calibrated:

February 21, 2012

Calibrated for DASY/EASY Systems

(Note: non-compatible with DASY2 system!)

Report No. RXA1208-0616HAC01

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ER3DV6- SN:2303

February 21, 2012

DASY/EASY - Parameters of Probe: ER3DV6 - SN:2303

Basic Calibration Parameters

	Sensor X	Sensor Y	Sensor Z	Unc (k=2)
Norm (µV/(V/m) ²)	1.40	1.42	1.43	± 10.1 %
DCP (mV) ⁸	100.7	99.2	104.7	

Modulation Calibration Parameters

UID	Communication System Name	PAR		A dB	B dB	C dB	VR mV	Unc ^E (k=2)
10000 CW	CW	0.00	X	0.00	0.00	1.00	111.4	±3.0 %
			Y	0.00	0.00	1.00	139.9	
			Z	0.00	0.00	1.00	133.1	

The reported uncertainty of measurement is stated as the standard uncertainty of measurement multiplied by the coverage factor k=2, which for a normal distribution corresponds to a coverage probability of approximately 95%.

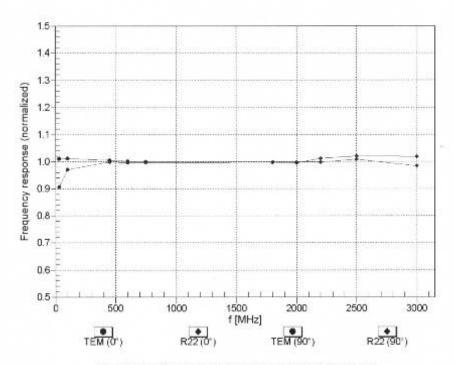
Numerical linearization parameter: uncertainty not required.
 Uncertainty is determined using the max. deviation from linear response applying rectangular distribution and is expressed for the square of the field value.

ER3DV6- SN:2303

February 21, 2012

Frequency Response of E-Field

(TEM-Cell:ifi110 EXX, Waveguide: R22)



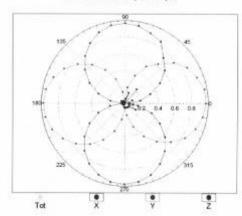
Uncertainty of Frequency Response of E-field: ± 6.3% (k=2)

ER3DV6-SN:2303

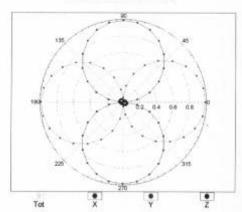
February 21, 2012

Receiving Pattern (ϕ), $\vartheta = 0^{\circ}$

f=600 MHz,TEM,0°

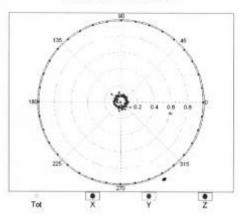


f=2500 MHz,R22,0°

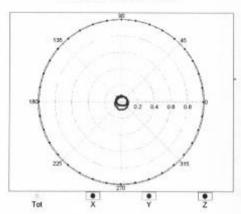


Receiving Pattern (6), 9 = 90°

f=600 MHz,TEM,90°



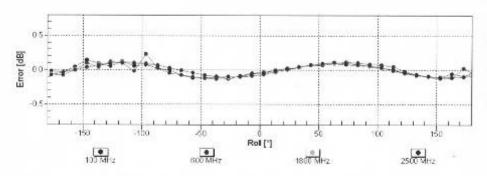
f=2500 MHz,R22,90°



ER3DV6- SN:2303

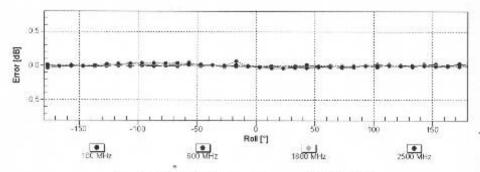
February 21, 2012

Receiving Pattern (ϕ), $\vartheta = 0^{\circ}$



Uncertainty of Axial Isotropy Assessment: ± 0.5% (k=2)

Receiving Pattern (\$\phi\$), 9 = 90°

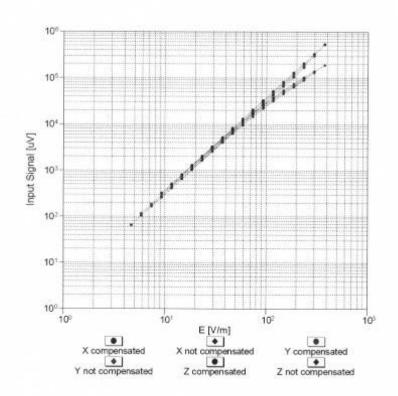


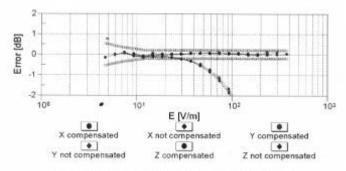
Uncertainty of Axial Isotropy Assessment: ± 0.5% (k=2)

ER3DV6- SN:2303

February 21, 2012

Dynamic Range f(E-field) (TEM cell , f = 900 MHz)





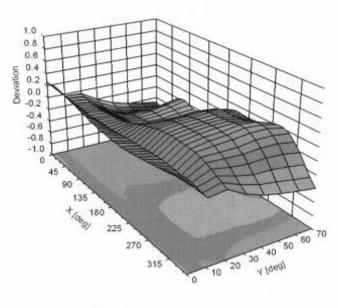
Uncertainty of Linearity Assessment: ± 0.6% (k=2)

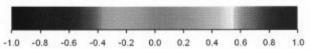
ER3DV6- SN:2303

February 21, 2012

Deviation from Isotropy in Air

Error (¢, 9), f = 900 MHz





Uncertainty of Spherical Isotropy Assessment: ± 2.6% (k=2)

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ER3DV6-- SN:2303

February 21, 2012

DASY/EASY - Parameters of Probe: ER3DV6 - SN:2303

Other Probe Parameters

Sensor Arrangement	Rectangular
Connector Angle (*)	-156.8
Mechanical Surface Detection Mode	enabled
Optical Surface Detection Mode	disabled
Probe Overall Length	337 mm
Probe Body Diameter	10 mm
Tip Length	10 mm
Tip Diameter	8 mm
Probe Tip to Sensor X Calibration Point	2.5 mm
Probe Tip to Sensor Y Calibration Point	2.5 mm
Probe Tip to Sensor Z Calibration Point	2.5 mm

Certificate No: ER3-2303_Feb12

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ANNEX D: H-Probe Calibration Certificate

Calibration Laboratory of Schmid & Partner Engineering AG Zeughausstrasse 43, 8004 Zurich, Switzerland





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TA Shanghai (Auden)

Certificate No: H3-6138_Feb12

Accreditation No.: SCS 108

S

CALIBRATION CERTIFICATE

Object

H3DV6 - SN:6138

Calibration procedure(s)

QA CAL-03.v6, QA CAL-25.v4

Calibration procedure for H-field probes optimized for close near field

evaluations in air

Calibration date:

February 21, 2012

This calibration certificate documents the traceability to national standards, which realize the physical units of measurements (SI). The measurements and the uncertainties with confidence probability are given on the following pages and are part of the certificate.

All calibrations have been conducted in the closed laboratory facility: environment temperature (22 ± 3)°C and humidity < 70%.

Calibration Equipment used (M&TE critical for calibration)

Primary Standards	ID	Cal Date (Certificate No.)	Scheduled Calibration
Power meter E4419B	GB41293874	31-Mar-11 (No. 217-01372)	Apr-12
Power sensor E4412A	MY41498087	31-Mar-11 (No. 217-01372)	Apr-12
Reference 3 dB Attenuator	SN: S5054 (3c)	29-Mar-11 (No. 217-01369)	Apr-12
Reference 20 dB Attenuator	SN: S5086 (20b)	29-Mar-11 (No. 217-01367)	Apr-12
Reference 30 dB Attenuator	SN: S5129 (30b)	29-Mar-11 (No. 217-01370)	Apr-12
Reference Probe H3DV6	SN: 6182	11-Oct-11 (No. H3-6182_Oct11)	Oct-12
DAE4	SN: 789	30-Jan-12 (No. DAE4-789_Jan12)	Jan-13
Secondary Standards	ID	Check Date (in house)	Scheduled Check
RF generator HP 8648C	US3642U01700 =	4-Aug-99 (in house check Apr-11)	In house check: Apr-13
Network Analyzer HP 8753E	US37390585	18-Oct-01 (in house check Oct-11)	In house check: Oct-12

Calibrated by: Claudio Leubler Laboratory Technician Technical Manager Approved by: Katia Pokovic Issued: February 23, 2012 This calibration certificate shall not be reproduced except in full without written approval of the laboratory

Certificate No: H3-6138_Feb12

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Report No. RXA1208-0616HAC01

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Calibration Laboratory of Schmid & Partner Engineering AG Zeughausstrasse 43, 8004 Zurich, Switzerland





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Swiss Calibration Service

Accreditation No.: SCS 108

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Glossary:

NORMx,y,z DCP CF sensitivity in free space

diode compression point crest factor (1/duty_cycle) of the RF signal

A, B, C

modulation dependent linearization parameters

Polarization o

φ rotation around probe axis

Polarization 9

9 rotation around an axis that is in the plane normal to probe axis (at measurement center),

i.e., 9 = 0 is normal to probe axis

Connector Angle

information used in DASY system to align probe sensor X to the robot coordinate system

Calibration is Performed According to the Following Standards:

 a) IEEE Std 1309-2005, "IEEE Standard for calibration of electromagnetic field sensors and probes, excluding antennas, from 9 kHz to 40 GHz", December 2005.

Methods Applied and Interpretation of Parameters:

- NORMx,y,z: Assessed for E-field polarization 9 = 0 for XY sensors and 9 = 90 for Z sensor (f ≤ 900 MHz in TEM-cell; f > 1800 MHz: R22 waveguide).
- X,Y,Z(f)_a0a1a2= X,Y,Z_a0a1a2* frequency_response (see Frequency Response Chart).
- DCPx,y,z: DCP are numerical linearization parameters assessed based on the data of power sweep with CW signal (no uncertainty required). DCP does not depend on frequency nor media.
- PAR: PAR is the Peak to Average Ratio that is not calibrated but determined based on the signal characteristics
- Ax,y,z; Bx,y,z; Cx,y,z, VRx,y,z; A, B, C are numerical linearization parameters assessed based on the data of power sweep for specific modulation signal. The parameters do not depend on frequency nor media. VR is the maximum calibration range expressed in RMS voltage across the diode.
- Spherical isotropy (3D deviation from isotropy): in a locally homogeneous field realized using an open waveguide setup.
- Sensor Offset: The sensor offset corresponds to the offset of virtual measurement center from the probe tip (on probe axis). No tolerance required.
- Connector Angle: The angle is assessed using the information gained by determining the X_a0a1a2 (no uncertainty required).

H3DV6 - SN:6138

February 21, 2012

Probe H3DV6

SN:6138

Manufactured:

July 3, 2002

Calibrated:

February 21, 2012

Calibrated for DASY/EASY Systems (Note: non-compatible with DASY2 system!)

H3DV6-SN:6138

February 21, 2012

DASY/EASY - Parameters of Probe: H3DV6 - SN:6138

Basic Calibration Parameters

		Sensor X	Sensor Y	Sensor Z	Unc (k=2)
Norm (A/m / √(mV))	a0	2.73E-003	2.93E-003	3.18E-003	± 5.1 %
Norm (A/m / √(mV))	a1	-5.89E-005	-2.38E-004	-2.18E-004	± 5.1 %
Norm (A/m / √(mV))	a2	-5.50E-006	-3.95E-006	-8.28E-007	± 5.1 %
DCP (mV) ⁸		93.5	92.1	94.8	

Modulation Calibration Parameters

UID	Communication System Name	PAR		A dB	B dB	C dB	VR mV	Unc ^b (k=2)
10000	CW	0.00	X	0.00	0.00	1.00	130.7	±3.3 %
			Y	0.00	0.00	1.00	125.5	
			Z	0.00	0.00	1.00	133.0	

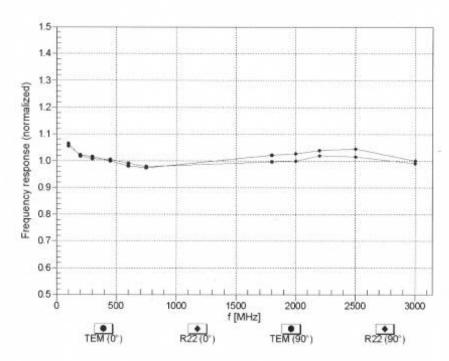
The reported uncertainty of measurement is stated as the standard uncertainty of measurement multiplied by the coverage factor k=2, which for a normal distribution corresponds to a coverage probability of approximately 95%.

⁶ Numerical linearization parameter: uncertainty not required.
⁶ Uncertainty is determined using the max, deviation from linear response applying rectangular distribution and is expressed for the square of the

H3DV6- SN:6138

February 21, 2012

Frequency Response of H-Field (TEM-Cell:ifi110 EXX, Waveguide: R22)

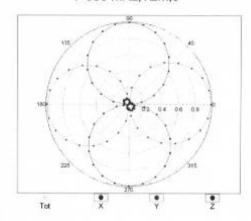


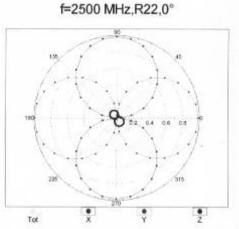
Uncertainty of Frequency Response of H-field: ± 6.3% (k=2)

H3DV6-SN:6138 February 21, 2012

Receiving Pattern (ϕ), $\vartheta = 0^{\circ}$

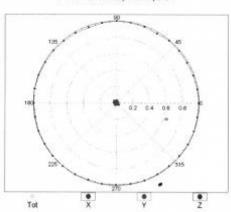




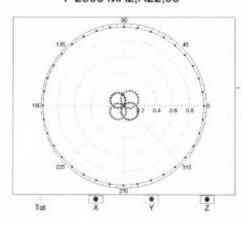


Receiving Pattern (\$\phi\$), \$\partial = 90°

f=600 MHz,TEM,90°



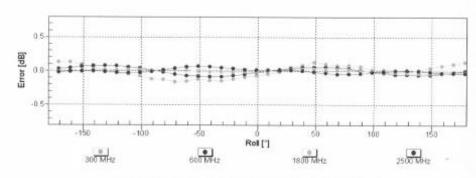
f=2500 MHz,R22,90°



H3DV6-SN:6138

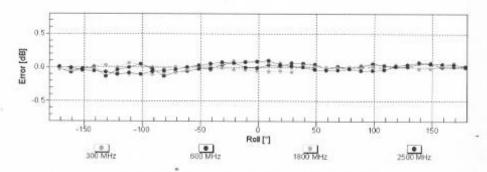
February 21, 2012

Receiving Pattern (ϕ), $\vartheta = 0^{\circ}$



Uncertainty of Axial Isotropy Assessment: ± 0.5% (k=2)

Receiving Pattern (ϕ), $\vartheta = 90^{\circ}$

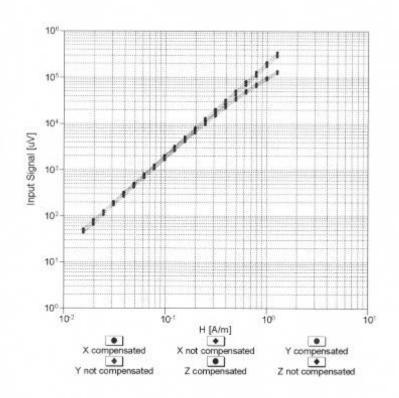


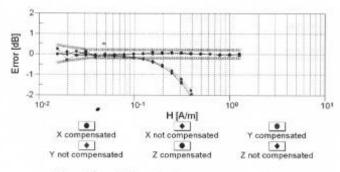
Uncertainty of Axial Isotropy Assessment: ± 0.5% (k=2)

H3DV6- SN:6138

February 21, 2012

Dynamic Range f(H-field) (TEM cell, f = 900 MHz)



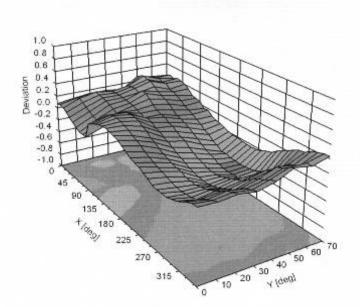


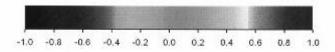
Uncertainty of Linearity Assessment: ± 0.6% (k=2)

H3DV6-SN:6138

February 21, 2012

Deviation from Isotropy in Air Error (ø, 3), f = 900 MHz





Uncertainty of Spherical Isotropy Assessment: ± 2.6% (k=2)

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H3DV6-SN:6138

February 21, 2012

DASY/EASY - Parameters of Probe: H3DV6 - SN:6138

Other Probe Parameters

Sensor Arrangement	Rectangular
Connector Angle (°)	168.6
Mechanical Surface Detection Mode	enabled
Optical Surface Detection Mode	disabled
Probe Overall Length	337 mm
Probe Body Diameter	10 mm
Tip Length	20 mm
Tip Diameter	6 mm
Probe Tip to Sensor X Calibration Point	3 mm
Probe Tip to Sensor Y Calibration Point	3 mm
Probe Tip to Sensor Z Calibration Point	3 mm

Certificate No: H3-6138_Feb12

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ANNEX E: CD835V3 Dipole Calibration Certificate

Calibration Laboratory of Schmid & Partner Engineering AG Zeughausstrasse 43, 8004 Zurich, Switzerland





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Accreditation No.: SCS 108

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Client

TA Shanghai (Auden)

Certificate No: CD835V3-1133 Feb12

CALIBRATION CERTIFICATE Object CD835V3 - SN: 1133 Calibration procedure(s) QA CAL-20.v6 Calibration procedure for dipoles in air Calibration date: February 21, 2012 This calibration certificate documents the traceability to national standards, which realize the physical units of measurements (SI). The measurements and the uncertainties with confidence probability are given on the following pages and are part of the certificate. All calibrations have been conducted in the closed laboratory facility: environment temperature (22 ± 3)°C and humidity < 70%. Calibration Equipment used (M&TE critical for calibration) ID W Primary Standards Cal Date (Certificate No.) Scheduled Calibration Power meter EPM-442A GB37480704 05-Oct-11 (No. 217-01451) Oct-12 Power sensor HP 8481A US37292783 05-Oct-11 (No. 217-01451) Oct-12 Probe ER3DV6 SN: 2336 29-Dec-11 (No. ER3-2336_Dec11) Dec-12 Probe H3DV6 SN: 6065 29-Dec-11 (No. H3-6065, Dec11) Dec-12 DAF4 SN: 781 20-Apr-11 (No. DAE4-781_Apr11) Apr-12 Secondary Standards ID# Check Date (in house) Scheduled Check Power meter Agilent 4419B SN: GB42420191 09-Oct-09 (in house check Oct-11) In house check: Oct-12 Power sensor HP 8482H SN: 3318A09450 09-Oct-09 (in house check Oct-11) In house check: Oct-12 Power sensor HP 8482A SN: US37295597 09-Oct-09 (in house check Oct-11) In house check: Oct-12 Network Analyzer HP 8753E US37390585 18-Oct-01 (in house check Oct-11) In house check: Oct-12 RF generator E4433B MY 41000675 * 03-Nov-04 (in house check Oct-11) In house check: Oct-13 Name Function Signature Calibrated by: Direce Iliev Laboratory Technician Approved by: Fin Bomhalt **R&D Director** Issued: February 22, 2012 This calibration certificate shall not be reproduced except in full without written approval of the laboratory

Certificate No: CD835V3-1133_Feb12

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Calibration Laboratory of Schmid & Partner Engineering AG Zeughausstrasse 43, 8004 Zurich, Switzerland





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Multilateral Agreement for the recognition of calibration certificates

Accreditation No.: SCS 108

References

[1] ANSI-C63.19-2007

American National Standard for Methods of Measurement of Compatibility between Wireless Communications Devices and Hearing Aids.

Methods Applied and Interpretation of Parameters:

- Coordinate System: y-axis is in the direction of the dipole arms. z-axis is from the basis of the antenna
 (mounted on the table) towards its feed point between the two dipole arms. x-axis is normal to the other axes.
 In coincidence with the standards [1], the measurement planes (probe sensor center) are selected to be at a
 distance of 10 mm above the top edge of the dipole arms.
- Measurement Conditions: Further details are available from the hardcopies at the end of the certificate. All
 figures stated in the certificate are valid at the frequency indicated. The forward power to the dipole connector
 is set with a calibrated power meter connected and monitored with an auxiliary power meter connected to a
 directional coupler. While the dipole under test is connected, the forward power is adjusted to the same level.
- Antenna Positioning: The dipole is mounted on a HAC Test Arch phantom using the matching dipole positioner with the arms horizontal and the feeding cable coming from the floor. The measurements are performed in a shielded room with absorbers around the setup to reduce the reflections. It is verified before the mounting of the dipole under the Test Arch phantom, that its arms are perfectly in a line. It is installed on the HAC dipole positioner with its arms parallel below the dielectric reference wire and able to move elastically in vertical direction without changing its relative position to the top center of the Test Arch phantom. The vertical distance to the probe is adjusted after dipole mounting with a DASY5 Surface Check job. Before the measurement, the distance between phantom surface and probe tip is verified. The proper measurement distance is selected by choosing the matching section of the HAC Test Arch phantom with the proper device reference point (upper surface of the dipole) and the matching grid reference point (tip of the probe) considering the probe sensor offset. The vertical distance to the probe is essential for the accuracy.
- Feed Point Impedance and Return Loss: These parameters are measured using a HP 8753E Vector Network Analyzer. The impedance is specified at the SMA connector of the dipole. The influence of reflections was eliminating by applying the averaging function while moving the dipole in the air, at least 70cm away from any obstacles.
- E-field distribution: E field is measured in the x-y-plane with an isotropic ER3D-field probe with 100 mW forward power to the antenna feed point. In accordance with [1], the scan area is 20mm wide, its length exceeds the dipole arm length (180 or 90mm). The sensor center is 10 mm (in z) above the top of the dipole arms. Two 3D maxima are available near the end of the dipole arms. Assuming the dipole arms are perfectly in one line, the average of these two maxima (in subgrid 2 and subgrid 8) is determined to compensate for any non-parallelity to the measurement plane as well as the sensor displacement. The E-field value stated as calibration value represents the maximum of the interpolated 3D-E-field, 10mm above the dipole surface.
- H-field distribution: H-field is measured with an isotropic H-field probe with 100mW forward power to the
 antenna feed point, in the x-y-plane. The scan area and sensor distance is equivalent to the E-field scan. The
 maximum of the field is available at the center (subgrid 5) above the feed point. The H-field value stated as
 calibration value represents the maximum of the interpolated H-field, 10mm above the dipole surface at the
 feed point.

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Measurement Conditions

DASY system configuration, as far as not given on page 1.

DASY Version	DASY5	V52.8.0
Extrapolation	Advanced Extrapolation	
Phantom	HAC Test Arch	
Distance Dipole Top - Probe Center	10mm	
Scan resolution	dx, dy = 5 mm	
Frequency	835MHz ± 1 MHz	
Input power drift	< 0.05 dB	

Maximum Field values

H-field 10 mm above dipole surface	condition	interpolated maximum
Maximum measured	100 mW input power	0.456 A / m ± 8.2 % (k=2)

E-field 10 mm above dipole surface	condition	Interpolated maximum
Maximum measured above high end	100 mW input power	161.4 V / m
Maximum measured above low end	100 mW input power	160.0 V / m
Averaged maximum above arm	100 mW input power	160.7 V / m ± 12.8 % (k=2)

Appendix

Antenna Parameters

Frequency	Return Loss	Impedance
800 MHz	15.7 dB	42.6 Ω - 13.5 jΩ
835 MHz	25,2 dB	$47.3 \Omega + 4.7 j\Omega$
900 MHz	17.9 dB	52.9 Ω - 12.8 jΩ
950 MHz	20,7 dB	46.3 Ω + 8.2 jΩ -
960 MHz	15.5 dB	52.8 Ω + 17.3 jΩ
A STATE OF THE STA		THE RESERVE THE PARTY OF THE PA

3.2 Antenna Design and Handling

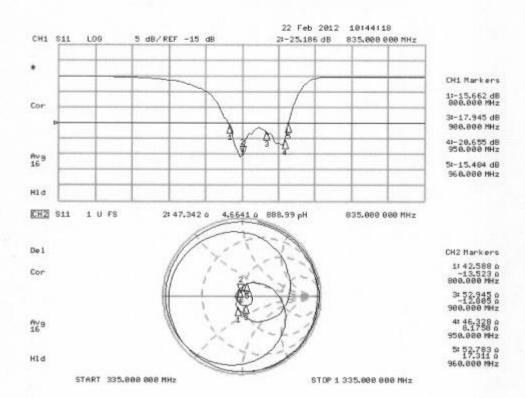
The calibration dipole has a symmetric geometry with a built-in two stub matching network, which leads to the enhanced bandwidth.

The dipole is built of standard semirigid coaxial cable. The internal matching line is open ended. The antenna is therefore open for DC signals.

Do not apply force to dipole arms, as they are liable to bend. The soldered connections near the feedpoint may be damaged. After excessive mechanical stress or overheating, check the impedance characteristics to ensure that the internal matching network is not affected.

After long term use with 40W radiated power, only a slight warming of the dipole near the feedpoint can be measured.

Impedance Measurement Plot



DASY5 H-field Result

Date: 21.02.2012

Test Laboratory: SPEAG Lab2

DUT: HAC-Dipole 835 MHz; Type: CD835V3; Serial: CD835V3 - SN: 1133

Communication System: CW; Frequency: 835 MHz Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 1$ kg/m³

Phantom section: RF Section

Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2007)

DASY52 Configuration:

- Probe: H3DV6 SN6065; ; Calibrated: 29.12.2011
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn781; Calibrated: 20.04.2011
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA; Serial: 1070
- DASY52 52.8.0(692); SEMCAD X 14.6.4(4989)

Dipole H-Field measurement @ 835MHz/H-Scan - 835MHz d=10mm/Hearing Aid Compatibility Test (41x361x1): Measurement grid: dx=5mm, dy=5mm Device Reference Point: 0, 0, -6.3 mm Reference Value = 0.49 V/m; Power Drift = 0.00 dB

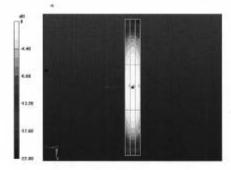
PMR not calibrated. PMF = 1.000 is applied.

H-field emissions = 0.46 A/m

Near-field category: M4 (AWF 0 dB)

PMF scaled H-field

Grid 1 M4 0.38 A/m		
Grid 4 M4 0.43 A/m		
Grid 7 M4 0.37 A/m	Grid 8 M4 0.40 A/m	Grid 9 M4 0.39 A/m



0 dB = 0.46A/m = -6.74 dB A/m

DASY5 E-field Result

Date: 21.02.2012

Test Laboratory: SPEAG Lab2

DUT: HAC-Dipole 835 MHz; Type: CD835V3; Serial: CD835V3 - SN: 1133

Communication System: CW; Frequency: 835 MHz

Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 1000$ kg/m³

Phantom section: RF Section

Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2007)

DASY52 Configuration:

- Probe: ER3DV6 SN2336; ConvF(1, 1, 1); Calibrated: 29.12.2011
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn781; Calibrated: 20.04.2011
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA; Serial: 1070
- DASY52 52.8.0(692); SEMCAD X 14.6.4(4989)

Dipole E-Field measurement @ 835MHz/E-Scan - 835MHz d=10mm/Hearing Aid Compatibility Test (41x361x1): Measurement grid: dx=5mm, dy=5mm

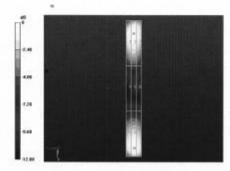
Device Reference Point: 0, 0, -6.3 mm Reference Value = 104.5 V/m; Power Drift = 0.00 dB PMR not calibrated PMF = 1.000 is applied.

E-field emissions = 161.4 V/m

Near-field category: M4 (AWF 0 dB)

PMF scaled E-field

Grid 1 M4	Grid 2 M4	Grid 3 M4
156.3 V/m	161.4 V/m	157.3 V/m
Grid 4 M4 86.05 V/m		
Grid 7 M4	Grid 8 M4	Grid 9 M4
151.4 V/m	160.0 V/m	157.8 V/m



0 dB = 161.4V/m = 44.16 dB V/m

ANNEX F: CD1880V3 Dipole Calibration Certificate

Calibration Laboratory of Schmid & Partner

Engineering AG Zeughausstrasse 43, 8004 Zurich, Switzerland





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Accreditation No.: SCS 108

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TA Shanghai (Auden) Certificate No: CD1880V3-1115 Feb12 **CALIBRATION CERTIFICATE** CD1880V3 - SN: 1115 Object QA CAL-20.v6 Calibration procedure(s) Calibration procedure for dipoles in air February 21, 2012 Calibration date: This calibration certificate documents the traceability to national standards, which realize the physical units of measurements (SI). The measurements and the uncertainties with confidence probability are given on the following pages and are part of the certificate. All calibrations have been conducted in the closed laboratory facility: environment temperature (22 ± 3)°C and humidity < 70%. Calibration Equipment used (M&TE critical for calibration) Primary Standards ID # Cal Date (Certificate No.) Scheduled Calibration Power meter EPM-442A GB37480704 05-Oct-11 (No. 217-01451) Oct-12 Power sensor HP 8481A US37292783 05-Oct-11 (No. 217-01451) Oct-12 Probe EB3DV6 SN: 2336 29-Dec-11 (No. ER3-2336_Dec11) Dec-12 Probe H3DV6 SN: 6065 29-Dec-11 (No. H3-6065_Dec11) Dec-12 SN: 781 20-Apr-11 (No. DAE4-781_Apr11) Apr-12 Secondary Standards Check Date (in house) Scheduled Check Power meter Agilent 4419B SN: GB42420191 09-Oct-09 (in house check Oct-11) In house check: Oct-12 Power sensor HP 8482H SN: 3318A09450 09-Oct-09 (in house check Oct-11) In house check: Oct-12 Power sensor HP 8482A SN: US37295597 09-Oct-09 (in house check Oct-11) In house check: Oct-12 US37390585 MY 41000675 Network Analyzer HP 8753E 18-Oct-01 (in house check Oct-11) In house check: Oct-12 RF generator E4433B 03-Nov-04 (in house check Oct-11) In house check: Oct-13 Name Function Calibrated by: Dimoe Iliev Laboratory Technician Approved by: Fin Bombott R&D Director Issued: February 22, 2012 This calibration certificate shall not be reproduced except in full without written approval of the laboratory

Certificate No: CD1880V3-1115_Feb12

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Accreditation No.: SCS 108

References

[1] ANSI-C63.19-2007

American National Standard for Methods of Measurement of Compatibility between Wireless Communications Devices and Hearing Aids.

Methods Applied and Interpretation of Parameters:

- Coordinate System: y-axis is in the direction of the dipole arms, z-axis is from the basis of the antenna
 (mounted on the table) towards its feed point between the two dipole arms, x-axis is normal to the other axes.
 In coincidence with the standards [1], the measurement planes (probe sensor center) are selected to be at a
 distance of 10 mm above the top edge of the dipole arms.
- Measurement Conditions: Further details are available from the hardcopies at the end of the certificate, All
 figures stated in the certificate are valid at the frequency indicated. The forward power to the dipole connector
 is set with a calibrated power meter connected and monitored with an auxiliary power meter connected to a
 directional coupler. While the dipole under test is connected, the forward power is adjusted to the same level.
- Antenna Positioning: The dipole is mounted on a HAC Test Arch phantom using the matching dipole positioner with the arms horizontal and the feeding cable coming from the floor. The measurements are performed in a shielded room with absorbers around the setup to reduce the reflections. It is verified before the mounting of the dipole under the Test Arch phantom, that its arms are perfectly in a line. It is installed on the HAC dipole positioner with its arms parallel below the dielectric reference wire and able to move elastically in vertical direction without changing its relative position to the top center of the Test Arch phantom. The vertical distance to the probe is adjusted after dipole mounting with a DASY5 Surface Check job. Before the measurement, the distance between phantom surface and probe tip is verified. The proper measurement distance is selected by choosing the matching section of the HAC Test Arch phantom with the proper device reference point (upper surface of the dipole) and the matching grid reference point (tip of the probe) considering the probe sensor offset. The vertical distance to the probe is essential for the accuracy.
- Feed Point Impedance and Return Loss: These parameters are measured using a HP 8753E Vector Network Analyzer. The impedance is specified at the SMA connector of the dipole. The influence of reflections was eliminating by applying the averaging function while moving the dipole in the air, at least 70cm away from any obstacles.
- E-field distribution: E field is measured in the x-y-plane with an isotropic ER3D-field probe with 100 mW forward power to the antenna feed point. In accordance with [1], the scan area is 20mm wide, its length exceeds the dipole arm length (180 or 90mm). The sensor center is 10 mm (in z) above the top of the dipole arms. Two 3D maxima are available near the end of the dipole arms. Assuming the dipole arms are perfectly in one line, the average of these two maxima (in subgrid 2 and subgrid 8) is determined to compensate for any non-parallelity to the measurement plane as well as the sensor displacement. The E-field value stated as calibration value represents the maximum of the interpolated 3D-E-field, 10mm above the dipole surface.
- H-field distribution: H-field is measured with an isotropic H-field probe with 100mW forward power to the
 antenna feed point, in the x-y-plane. The scan area and sensor distance is equivalent to the E-field scan. The
 maximum of the field is available at the center (subgrid 5) above the feed point. The H-field value stated as
 calibration value represents the maximum of the interpolated H-field, 10mm above the dipole surface at the
 feed point.

Measurement Conditions

DASY system configuration, as far as not given on page 1.

DASY Version	DASY5	V52.8.0
Extrapolation	Advanced Extrapolation	
Phantom	HAC Test Arch	
Distance Dipole Top - Probe Center	10mm	
Scan resolution	dx, dy = 5 mm	
Frequency	1880MHz ± 1 MHz	
Input power drift	< 0.05 dB	

Maximum Field values

H-field 10 mm above dipole surface	condition	interpolated maximum	
Maximum measured	100 mW input power	0.473 A / m ± 8.2 % (k=2)	

E-field 10 mm above dipole surface	condition	Interpolated maximum
Maximum measured above high end	100 mW input power	143.4 V / m
Maximum measured above low end	100 mW input power	139.6 V / m
Averaged maximum above arm	100 mW input power	141.5 V / m ± 12.8 % (k=2)

Appendix

Antenna Parameters

Frequency	Return Loss	Impedance	
1730 MHz	30.5 dB	52.6 Ω + 1.5 jΩ	
1880 MHz	21.7 dB	$46.1 \Omega + 6.9 j\Omega$	
1900 MHz	22.0 dB	$47.6 \Omega + 7.4 j\Omega$	
1950 MHz	29.8 dB 49		
2000 MHz	18.9 dB	41.3 Ω + 5.6 jΩ	

3.2 Antenna Design and Handling

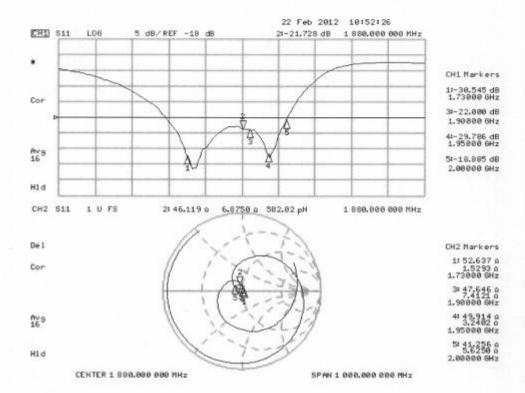
The calibration dipole has a symmetric geometry with a built-in two stub matching network, which leads to the enhanced bandwidth.

The dipole is built of standard semirigid coaxial cable. The internal matching line is open ended. The antenna is therefore open for DC signals.

Do not apply force to dipole arms, as they are liable to bend. The soldered connections near the feedpoint may be damaged. After excessive mechanical stress or overheating, check the impedance characteristics to ensure that the internal matching network is not affected.

After long term use with 40W radiated power, only a slight warming of the dipole near the feedpoint can be measured.

Impedance Measurement Plot



DASY5 H-field Result

Date: 21.02.2012

Test Laboratory: SPEAG Lab2

DUT: HAC Dipole 1880 MHz; Type: CD1880V3; Serial: CD1880V3 - SN: 1115

Communication System: CW; Frequency: 1880 MHz Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 1$ kg/m³

Phantom section: RF Section

Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2007)

DASY52 Configuration:

- Probe: H3DV6 SN6065; ; Calibrated: 29.12.2011
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn781; Calibrated: 20.04.2011
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA; Serial: 1070
- DASY52 52.8.0(692); SEMCAD X 14.6.4(4989)

Dipole H-Field measurement @ 1880MHz/H-Scan - 1880MHz d=10mm/Hearing Aid Compatibility Test (41x181x1): Measurement grid: dx=5mm, dy=5mm

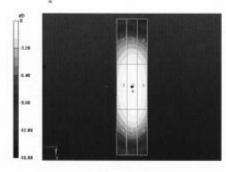
Device Reference Point: 0, 0, -6.3 mm Reference Value = 0.50 V/m; Power Drift = -0.01 dB

PMR not calibrated. PMF = 1.000 is applied.

H-field emissions = 0.47 A/m Near-field category: M2 (AWF 0 dB)

PMF scaled H-field

		Grid 3 M2 0.41 A/m
	Grid 5 M2 0.47 A/m	Grid 6 M2 0.46 A/m
Grid 7 M2 0.41 A/m	Grid 8 M2 0.44 A/m	Grid 9 M2 0.42 A/m



0 dB = 0.47 A/m = -6.56 dB A/m

DASY5 E-field Result

Date: 21.02.2012

Test Laboratory: SPEAG Lab2

DUT: HAC Dipole 1880 MHz; Type: CD1880V3; Serial: CD1880V3 - SN: 1115

Communication System: CW; Frequency: 1880 MHz

Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 1000 \text{ kg/m}^3$

Phantom section: RF Section

Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2007)

DASY52 Configuration:

- Probe: ER3DV6 SN2336; ConvF(1, 1, 1); Calibrated: 29.12.2011
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn781; Calibrated: 20.04.2011
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA; Serial: 1070
- DASY52 52.8.0(692); SEMCAD X 14.6.4(4989)

Dipole E-Field measurement @ 1880MHz/E-Scan - 1880MHz d=10mm/Hearing Aid Compatibility Test (41x181x1): Measurement grid: dx=5mm, dy=5mm

Device Reference Point: 0, 0, -6.3 mm Reference Value = 161.1 V/m; Power Drift = -0.01 dB

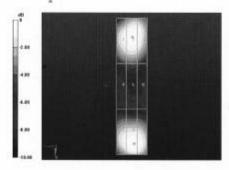
PMR not calibrated. PMF = 1.000 is applied.

E-field emissions = 143.4 V/m

Near-field category: M2 (AWF 0 dB)

PMF scaled E-field

Grid 1 M2	Grid 2 M2	Grid 3 M2
134.3 V/m	139.6 V/m	136.5 V/m
Grid 4 M3	Grid 5 M3	Grid 6 M3
90.34 V/m	93.17 V/m	89.93 V/m
Grid 7 M2	Grid 8 M2	Grid 9 M2
134.3 V/m	143.4 V/m	141.8 V/m



0 dB = 143.4V/m = 43.13 dB V/m

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ANNEX G: DAE4 Calibration Certificate

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Client

TA Shanghai (Auden)

Certificate No: DAE4-1317_Jan12

Accreditation No.: SCS 108

Object	DAE4 - SD 000 D	04 BJ - SN: 1317	
Calibration procedure(s)	QA CAL-06.v24 Calibration proced	dure for the data acquisition e	electronics (DAE)
Calibration date:	January 23, 2012		
	ated in the closed laboratory	obability are given on the following page facility: environment temperature (22 ±	
	ID # Cal Date (Certificate No.)		
		Cal Date (Certificate No.)	Scheduled Calibration
	SN: 0810278	Cal Date (Certificate No.) 28-Sep-11 (No:11450)	Scheduled Calibration Sep-12
eithley Multimeter Type 2001			
Ceithley Multimeter Type 2001 Secondary Standards	SN: 0810278	28-Sep-11 (No:11450)	Sep-12
Ceithley Multimeter Type 2001 Secondary Standards	SN: 0810278	28-Sep-11 (No:11450) Check Date (in house)	Sep-12 Scheduled Check
Ceithley Multimeter Type 2001 Secondary Standards	SN: 0810278	28-Sep-11 (No:11450) Check Date (in house)	Sep-12 Scheduled Check
Ceithley Multimeter Type 2001 Secondary Standards Calibrator Box V2.1	SN: 0810278 ID # SE UWS 053 AA 1001	28-Sep-11 (No:11450) Check Date (in house) 05-Jan-12 (in house check) Function Technician	Sep-12 Scheduled Check In house check: Jan-13 Signature
Primary Standards Keithley Multimeter Type 2001 Secondary Standards Calibrator Box V2.1 Calibrated by:	SN: 0810278 ID # SE UWS 053 AA 1001	28-Sep-11 (No:11450) Check Date (in house) 05-Jan-12 (in house check) Function Technician	Sep-12 Scheduled Check In house check: Jan-13

Certificate No: DAE4-1317_Jan12

Report No. RXA1208-0616HAC01

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Glossary

DAE

data acquisition electronics

Connector angle

information used in DASY system to align probe sensor X to the robot

coordinate system.

Methods Applied and Interpretation of Parameters

- DC Voltage Measurement: Calibration Factor assessed for use in DASY system by comparison with a calibrated instrument traceable to national standards. The figure given corresponds to the full scale range of the voltmeter in the respective range.
- Connector angle: The angle of the connector is assessed measuring the angle mechanically by a tool inserted. Uncertainty is not required.
- The following parameters as documented in the Appendix contain technical information as a result from the performance test and require no uncertainty.
 - DC Voltage Measurement Linearity: Verification of the Linearity at +10% and -10% of the nominal calibration voltage. Influence of offset voltage is included in this measurement.
 - Common mode sensitivity: Influence of a positive or negative common mode voltage on the differential measurement.
 - Channel separation: Influence of a voltage on the neighbor channels not subject to an input voltage.
 - AD Converter Values with inputs shorted: Values on the internal AD converter corresponding to zero input voltage
 - Input Offset Measurement. Output voltage and statistical results over a large number of zero voltage measurements.
 - Input Offset Current: Typical value for information; Maximum channel input offset current, not considering the input resistance.
 - Input resistance: Typical value for information: DAE input resistance at the connector, during internal auto-zeroing and during measurement.
 - Low Battery Alarm Voltage: Typical value for information. Below this voltage, a battery alarm signal is generated.
 - Power consumption: Typical value for information. Supply currents in various operating modes.

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DC Voltage Measurement

A/D - Converter Resolution nominal

High Range: 1LSB =

 $B = 6.1 \mu V$,

full range = +100...+300 mV

Low Range: 1LSB = 61nV

full range = -1.....+3mV

DASY measurement parameters: Auto Zero Time; 3 sec; Measuring time; 3 sec

Calibration Factors	x	Y	Z
High Range	404.064 ± 0.1% (k=2)	404.056 ± 0.1% (k=2)	403.955 ± 0.1% (k=2)
Low Range	3.98762 ± 0.7% (k=2)	3.98737 ± 0.7% (k=2)	3.98343 ± 0.7% (k=2)

Connector Angle

Connector Angle to be used in DASY system	117.0°±1°

Certificate No: DAE4-1317_Jan12

Appendix

1. DC Voltage Linearity

High Range	Reading (μV)	Difference (μV)	Error (%)
Channel X + Input	199992.18	-1.75	-0.00
Channel X + Input	20001.35	0.46	0.00
Channel X - Input	-19997.31	1.96	-0.01
Channel Y + Input	199993.18	-1.24	-0.00
Channel Y + Input	20001.40	0.60	0.00
Channel Y - Input	-20000.04	-0.70	0.00
Channel Z + Input	199991.58	-2.43	-0.00
Channel Z + Input	19999.62	-1.14	-0.01
Channel Z - Input	-20001.31	-1.83	0.01

Low Range	Reading (μV)	Difference (μV)	Error (%)
Channel X + Input	2000.74	-0.89	-0.04
Channel X + Input	202.18	-0.01	-0.01
Channel X - Input	-197.58	0.36	-0.18
Channel Y + Input	2000.34	-1.20	-0.06
Channel Y + Input	199.67	-2.39	-1.18
Channel Y - Input	-197.64	0.32	-0.16
Channel Z + Input	2000.69	-0.78	-0.04
Channel Z + Input	200.84	-1.16	-0.57
Channel Z - Input	-198.45	-0.47	0.24

2. Common mode sensitivity

DASY measurement parameters: Auto Zero Time: 3 sec; Measuring time: 3 sec

	Common mode Input Voltage (mV)	High Range Average Reading (μV)	Low Range Average Reading (μV)
Channel X	200	-23.40	-24.98
	- 200 *	28.01	26.12
Channel Y	200	-2.57	-2.75
	- 200	1.67	1.31
Channel Z	200	-11.92	-11.43
	- 200	9.80	9.45

3. Channel separation

DASY measurement parameters: Auto Zero Time: 3 sec; Measuring time: 3 sec

	Input Voltage (mV)	Channel X (μV)	Channel Y (µV)	Channel Z (µV)
Channel X	200		-2.15	-4.41
Channel Y	200	7.18		-2.47
Channel Z	200	7.44	5.46	

Certificate No: DAE4-1317_Jan12

4. AD-Converter Values with inputs shorted

DASY measurement parameters: Auto Zero Time; 3 sec; Measuring time; 3 sec

	High Range (LSB)	Low Range (LSB)
Channel X	16081	17027
Channel Y	16103	16170
Channel Z	16221	16651

5. Input Offset Measurement

DASY measurement parameters: Auto Zero Time: 3 sec; Measuring time: 3 sec

Input $10M\Omega$

	Average (μV)	min. Offset (μV)	max. Offset (μV)	Std. Deviation (µV)
Channel X	-0.45	-1.32	0.40	0.32
Channel Y	-2.63	-3.99	-1.68	0.42
Channel Z	-0.67	-3.07	1.36	0.50

6. Input Offset Current

Nominal Input circuitry offset current on all channels: <25fA

7. Input Resistance (Typical values for information)

	Zeroing (kOhm)	Measuring (MOhm)
Channel X	200	200
Channel Y	200	200
Channel Z	200	200

8. Low Battery Alarm Voltage (Typical values for information)

Typical values	Alarm Level (VDC)	
Supply (+ Vcc)	+7.9	
Supply (- Vcc)	-7.6	

9. Power Consumption (Typical values for information)

Typical values	Switched off (mA)	Stand by (mA)	Transmitting (mA)
Supply (+ Vcc)	+0.01	+6	+14
Supply (- Vcc)	-0.01	-8	-9